

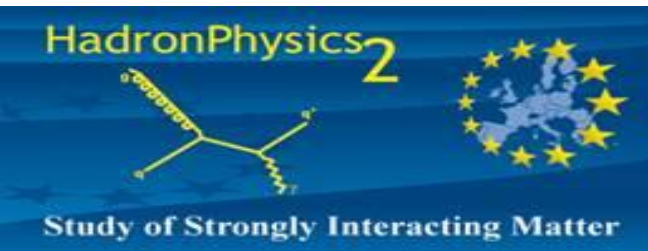
SIDDHARTA - 2 STATUS REPORT

Johann Zmeskal
for the SIDDHARTA-2 Collaboration

53nd LNF-INFN SCIENTIFIC COMMITTEE
May 9, 2017

SIDDHARTA-2 Collaboration

Silicon Drift Detector for Hadronic Atom Research by Timing Applications



LNF- INFN, Frascati, Italy
SMI- ÖAW, Vienna, Austria
Politecnico, Milano, Italy
IFIN – HH, Bucharest, Romania
TUM, Munich, Germany, Germany
RIKEN, Japan
Univ. Tokyo, Japan
Victoria Univ., Canada
Univ. Zagreb, Croatia
Helmholtz Inst. Mainz, Germany
CNRS, Paris, France
Indian Inst. of Science, Bangalore, India



*Ministero degli Affari Esteri
e della Cooperazione Internazionale*
StrangeMatter

CONTENT

Scientific Motivation

SIDDHARTA-2 apparatus – status with time lines

- Mounting frame
- Beam pipe
- Luminosity monitor
- Kaon trigger
- Cooling system
- Vacuum chamber
- Cryogenic target
- SDD X-ray detector
- Veto system

Overall time schedule

The scientific goal of SIDDHARTA-2

To perform precision measurements of **kaonic atoms X-ray transitions**

- unique information about QCD in the non-perturbative regime in the strangeness sector not obtainable otherwise

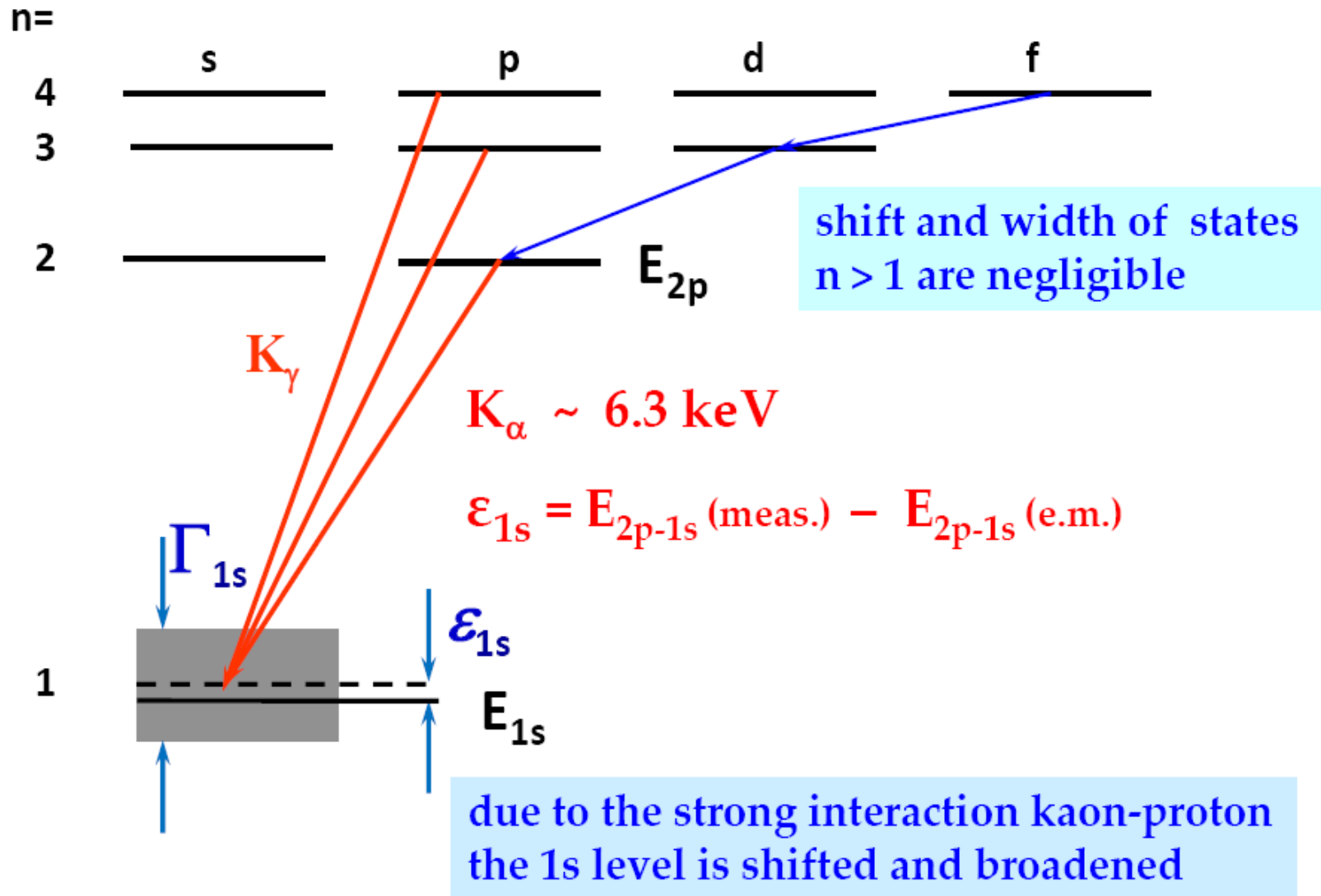
Starting with the precision measurement *of shift* and *width*

- **first measurement of kaonic deuterium**

to extract the antikaon-nucleon isospin dependent scattering lengths

- chiral symmetry breaking, EOS for neutron stars

X-RAY TRANSITIONS TO THE 1s STATE

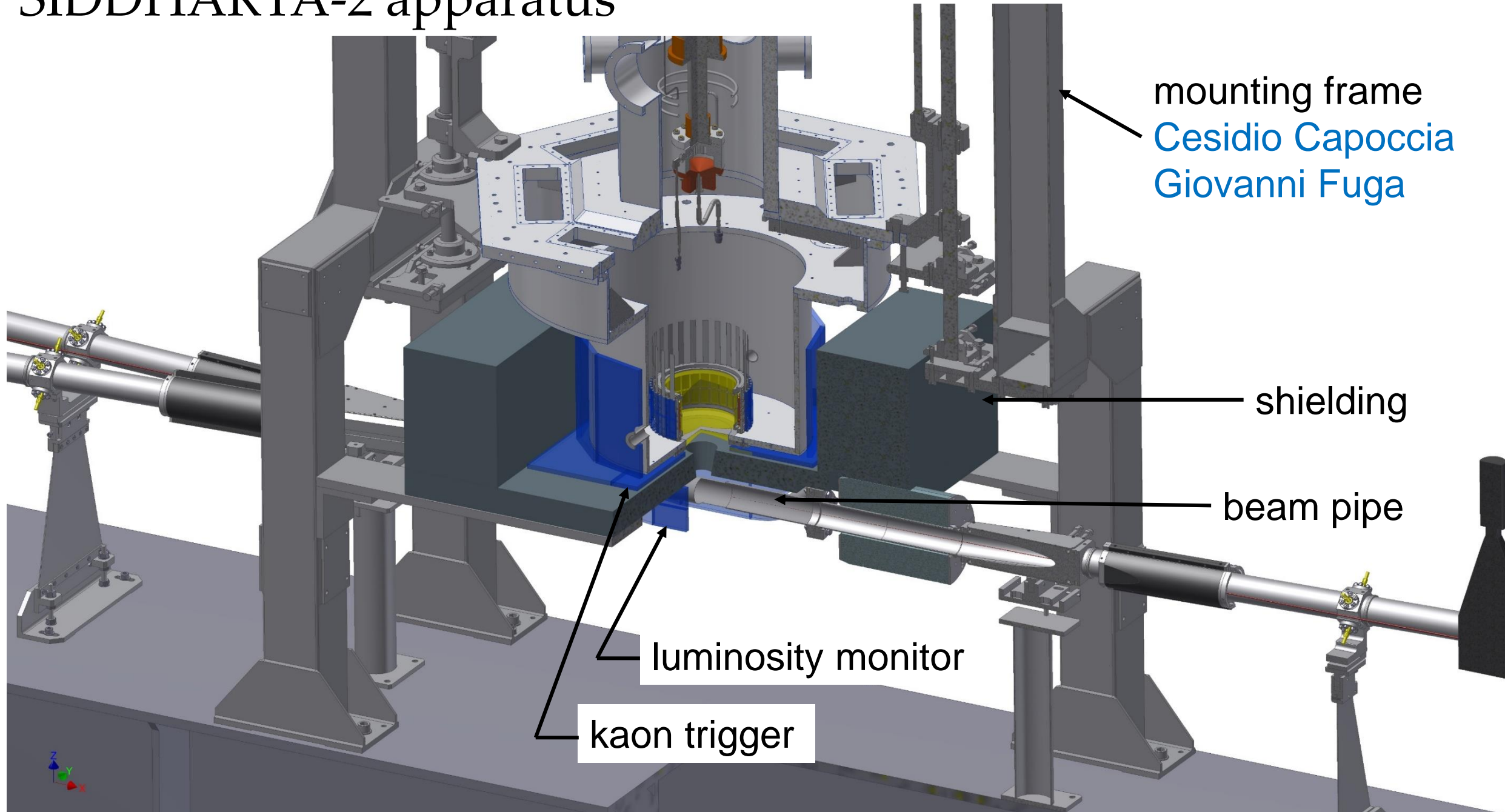


SIDDHARTA-2 setup

- Mounting frame
- Beam pipe
- Luminosity monitor
- Kaon trigger

□ Platform

SIDDHARTA-2 apparatus



mounting frame
Cesidio Capoccia
Giovanni Fuga

shielding

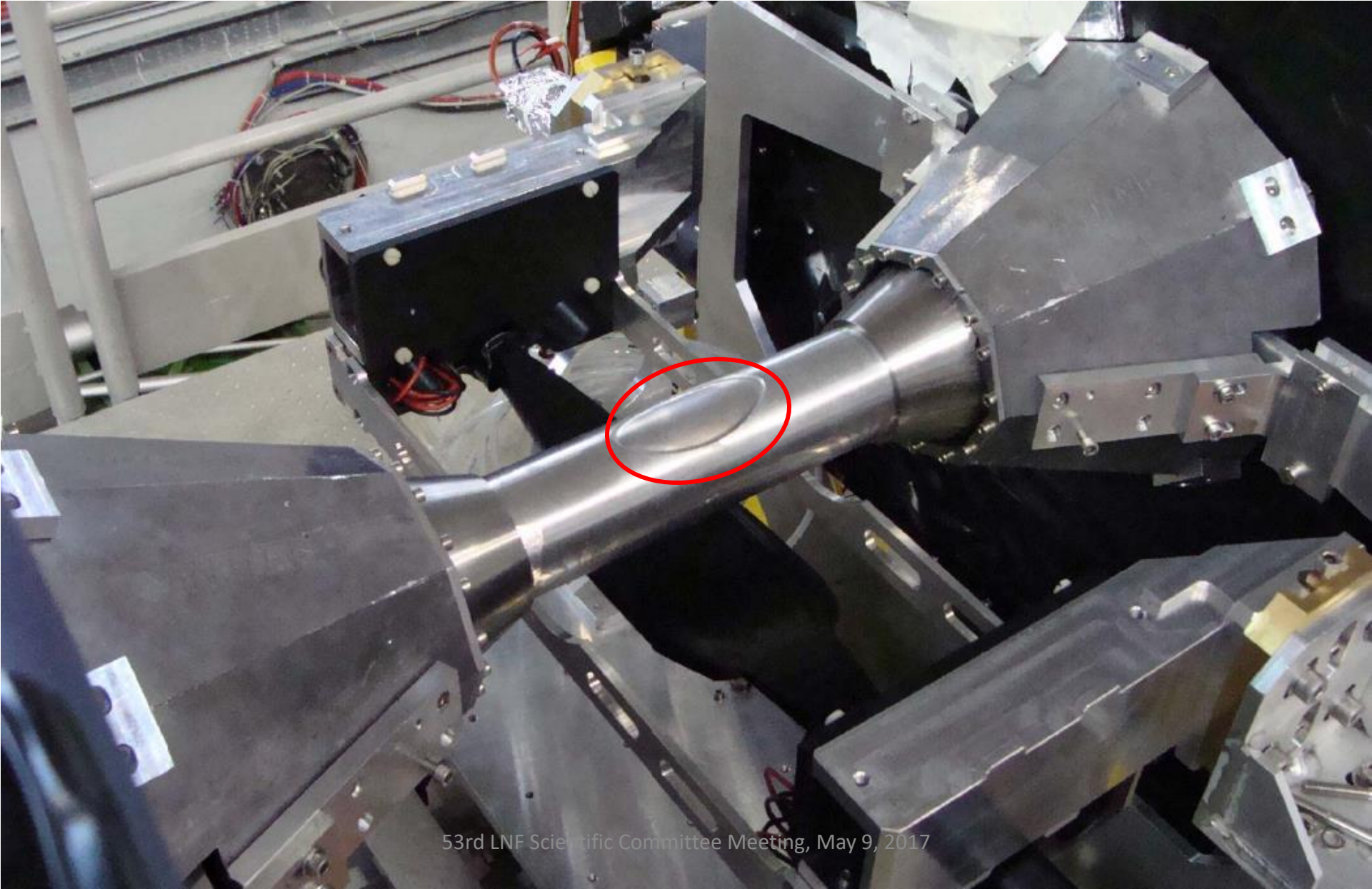
beam pipe

luminosity monitor

kaon trigger

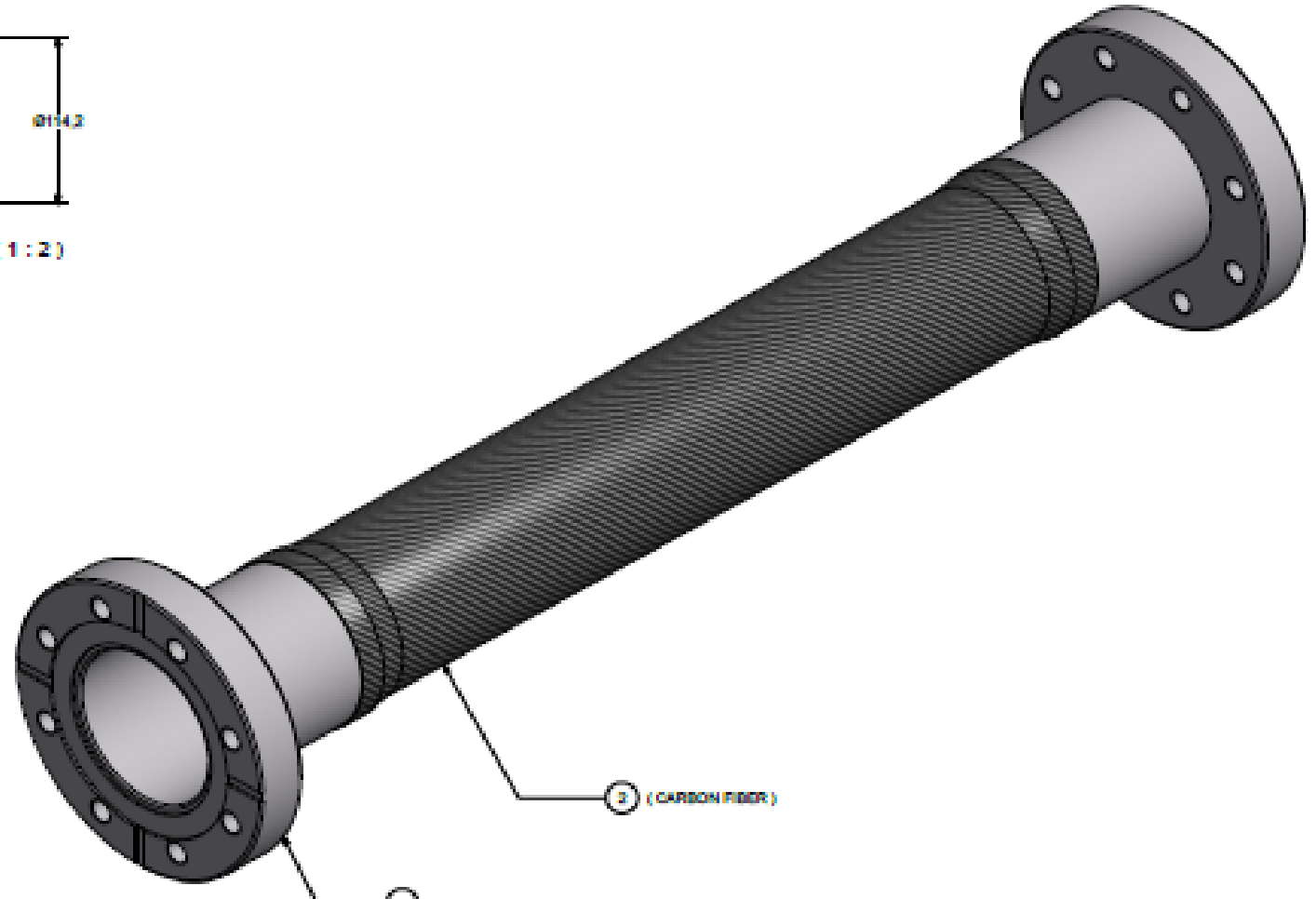
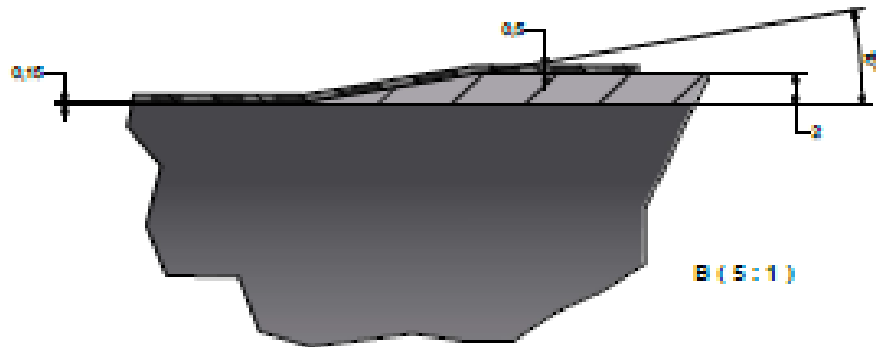
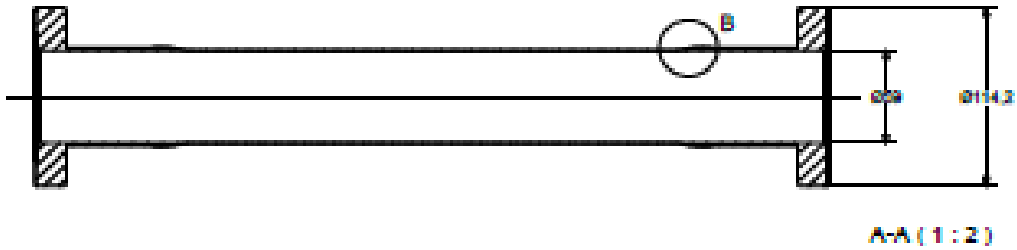
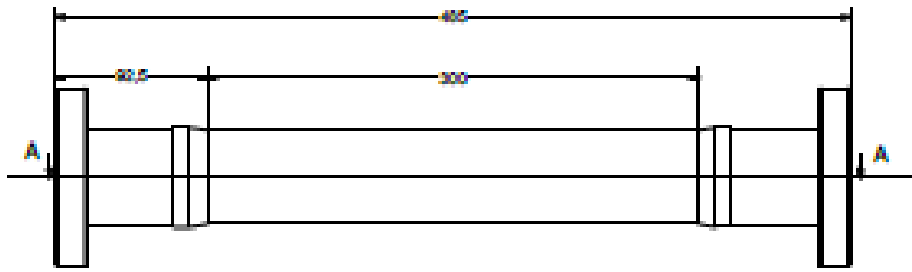


SIDDHARTA – beam pipe



SIDDHARTA-2 beam pipe

- ✓ design / quotation
 - final diameter to be decided



SIDDHARTA-2 - Luminosity monitor (based on kaons)

Size: $8 \times 8 \text{ cm}^2$ both side of the beam pipe,
made of 2 pieces $8 \times 4 \text{ cm}^2$, thickness = 2 mm
distance $y = \pm 4 \text{ cm}$ off beam

➤ **Coincidence rate:**

25.7 % per charged kaon pair

single rate at the boost side: 42.7 %

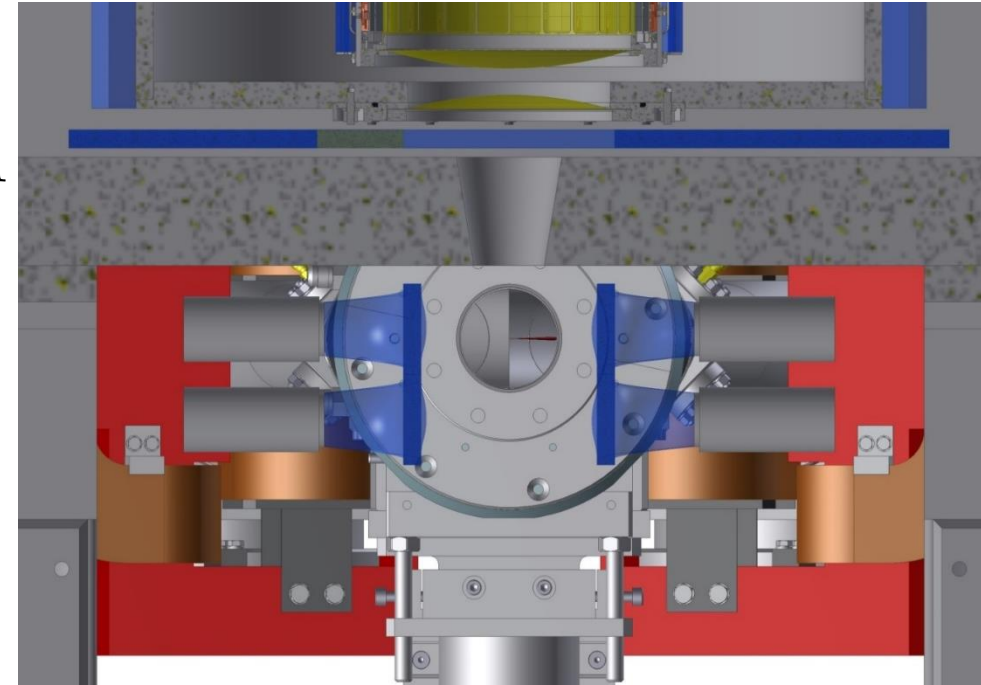
single rate at the anti-boost side: 32.3 %

With a luminosity $L = 10^{32}$

→ 37 Hz (coincidence) / 62 Hz (on boost-side)

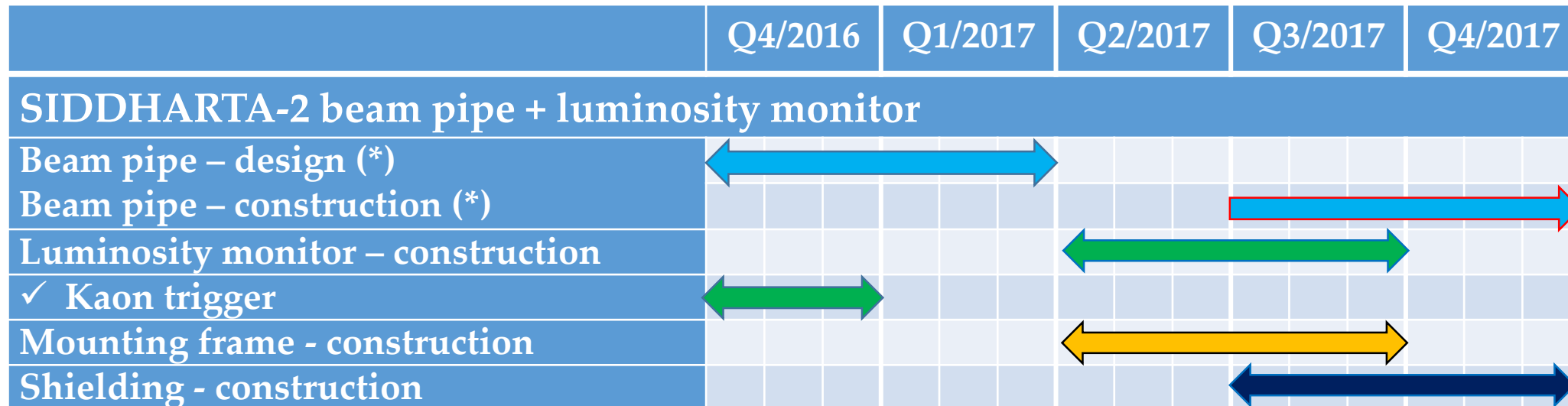
in 5 seconds:

185 counts (7%) / 310 counts (5.7%)



- prototype under construction, BTF timing test summer 2017

Gantt chart SIDDHARTA-2: beam pipe + luminosity monitor + mounting frame



(*) Beam pipe – final diameter has to be fixed, depending on the final IR for SIDDHARTA-2

SIDDHARTA-2 setup

- Cooling systems
- Vacuum chamber + feedthroughs
- Cryogenic target

SIDDHARTA-2 cooling

✓ Target + SDD cooling:

1 Leybold MD10 – 16 W @ 20 K
target cell and SDDs will be cooled
via ultra pure aluminum bars

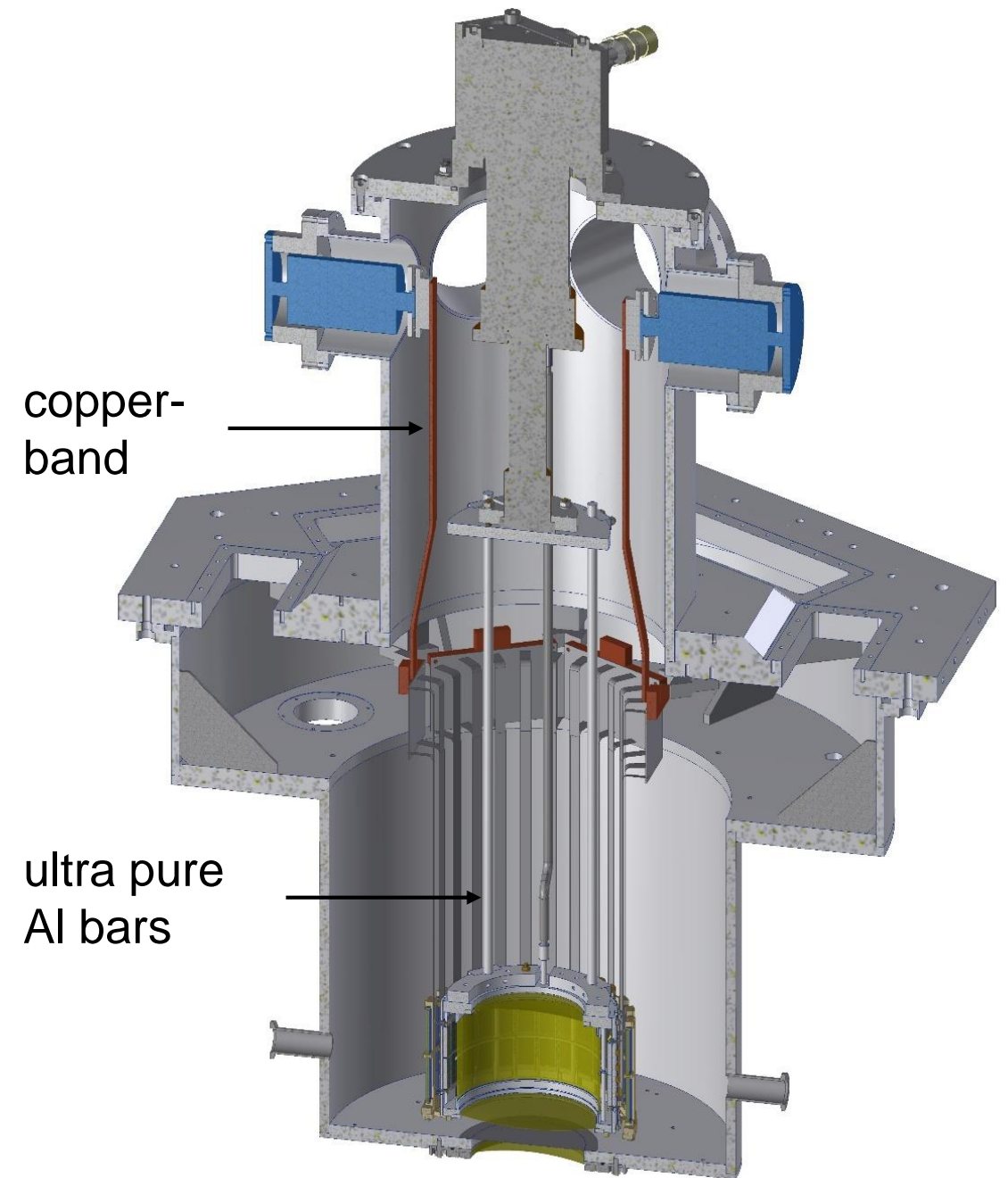
$$T_{TC} = 30 \text{ K}$$

$$T_{SDD} = 50 \text{ K}$$

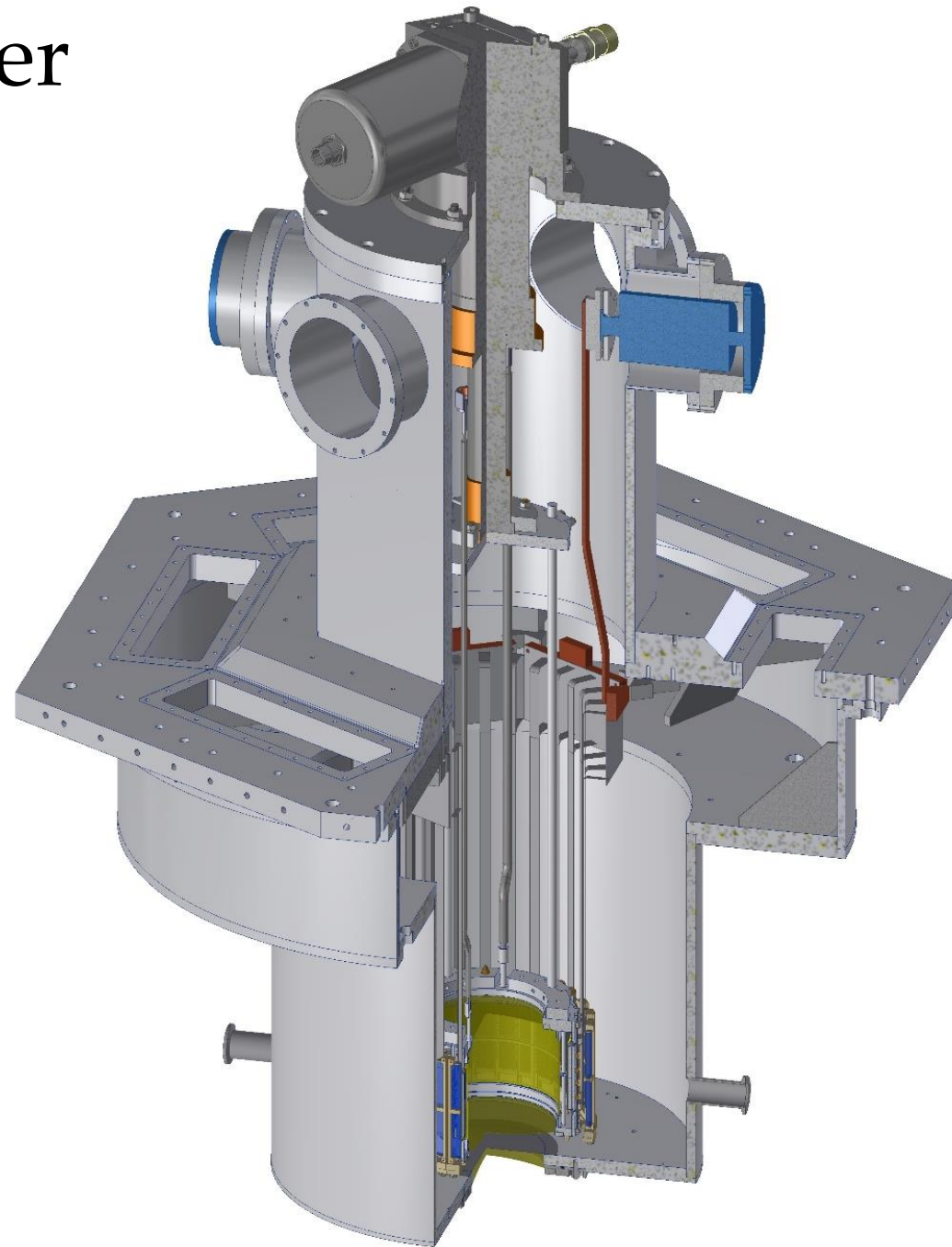
✓ Line driver boards:

2 CryoTiger – 30 W @ 120 K
copper-band cooling lines

$$T_{LD} = 120 \text{ K}$$



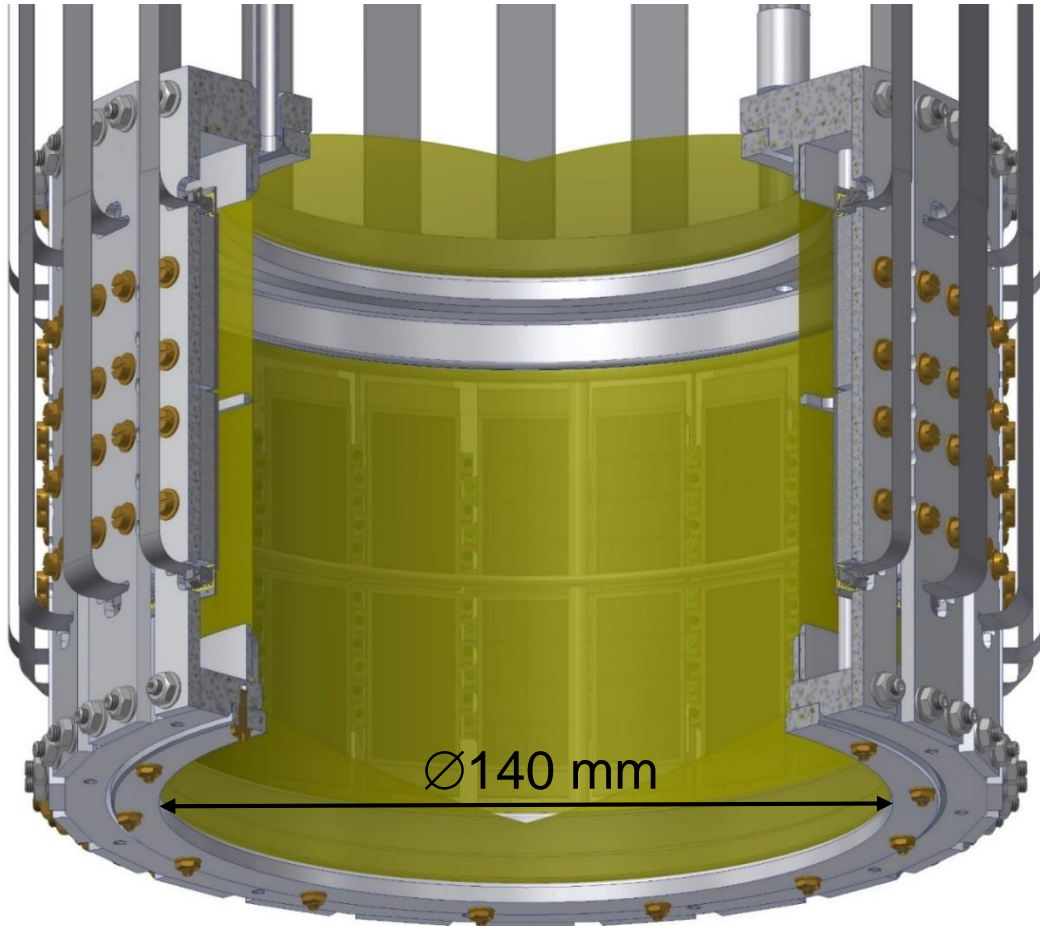
SIDDHARTA-2 vacuum chamber



SIDDHARTA-2 cryogenic target

Working temperature: 30 K

Working pressure : 0.3 MPa



Pressurised for 16 days
with $P = 0.3$ MPa (overP)

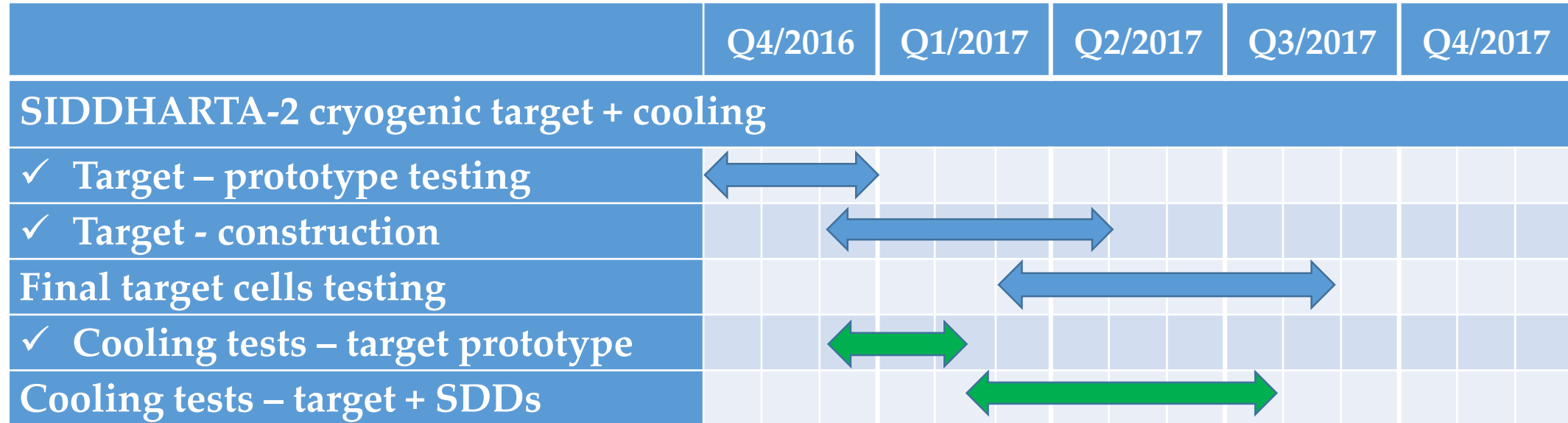
Cooling/pressure test

- 2.5 weeks 30 K / 0.19 MPa
- 3.5 days 30 K / 0.31 MPa



- Target cell wall is made of a 2-Kapton layer structure (25 μm + 25 μm + Araldit < 100 μm)

Gantt chart SIDDHARTA-2: target



SIDDHARTA-2 setup

- SDD X-ray detector

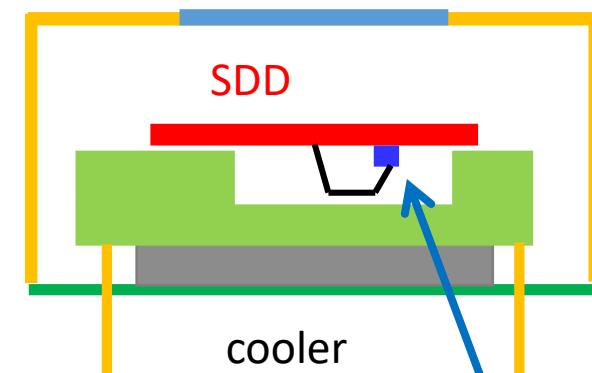
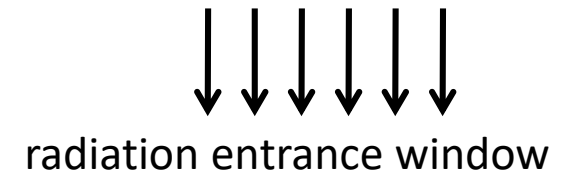
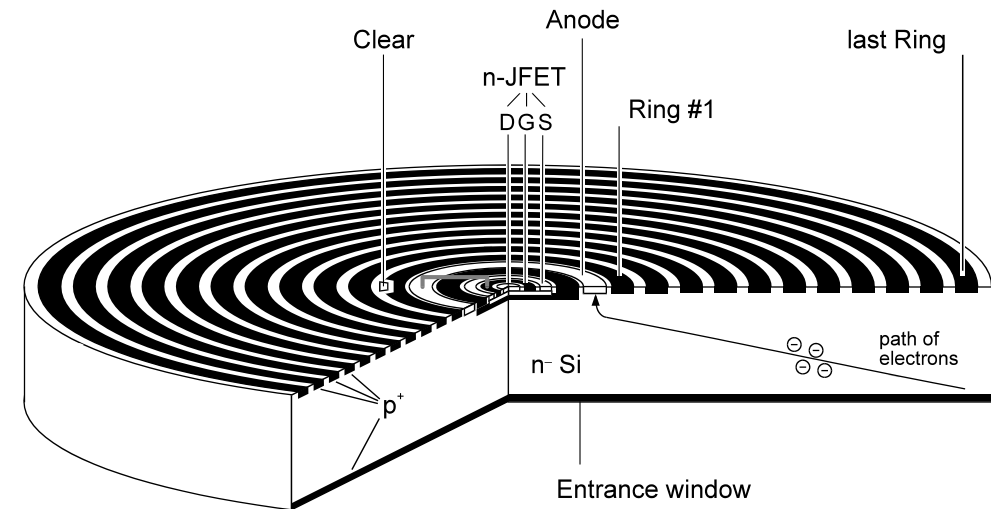
The “new” Silicon Drift Detector

➤ SIDDHARTA

- JFET integrated on SDD
- lowest total anode capacitance
- limited JFET performance
- sophisticated SDD+JFET technology

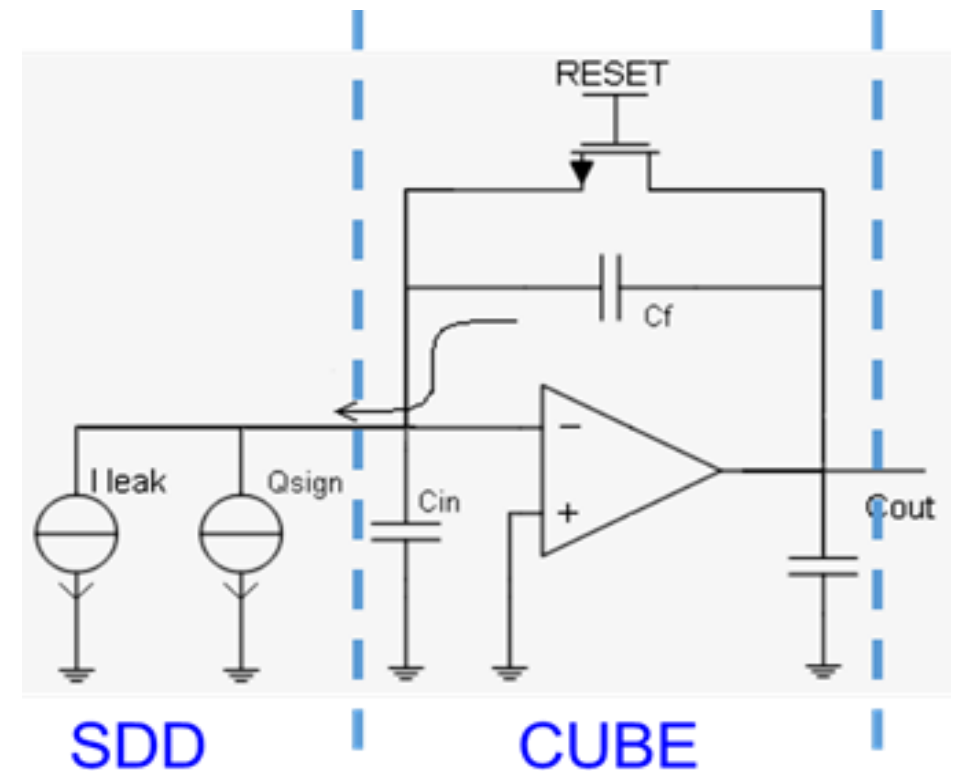
➤ SIDDHARTA-2

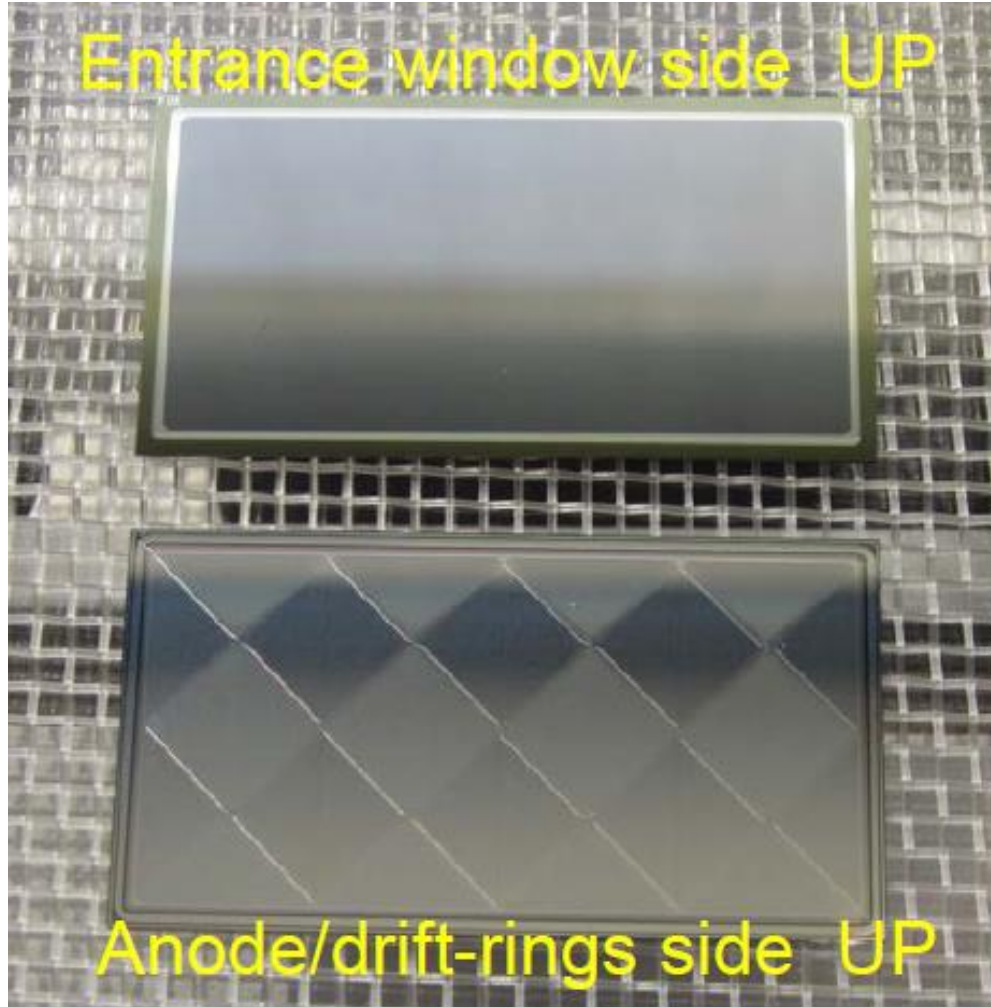
- external CUBE preamplifier (MOSFET input transistor)
- larger total anode capacitance
- better than FET performances
- standard SDD technology



The CUBE preamplifier

- A full **CMOS preamplifier** is mounted on ceramic board - connected via bonding
- The **CUBE** replaces the JFET, which was direct implanted on the anode side on the SIDDHARTA type SDDs
- Short bonding lines from CUBE to SDD, no difference in the detector performance
- Advantage, the preamplifier is connected close to the SDD and not only the FET → ASIC of analogue processing can be placed relatively up to ~100 cm away



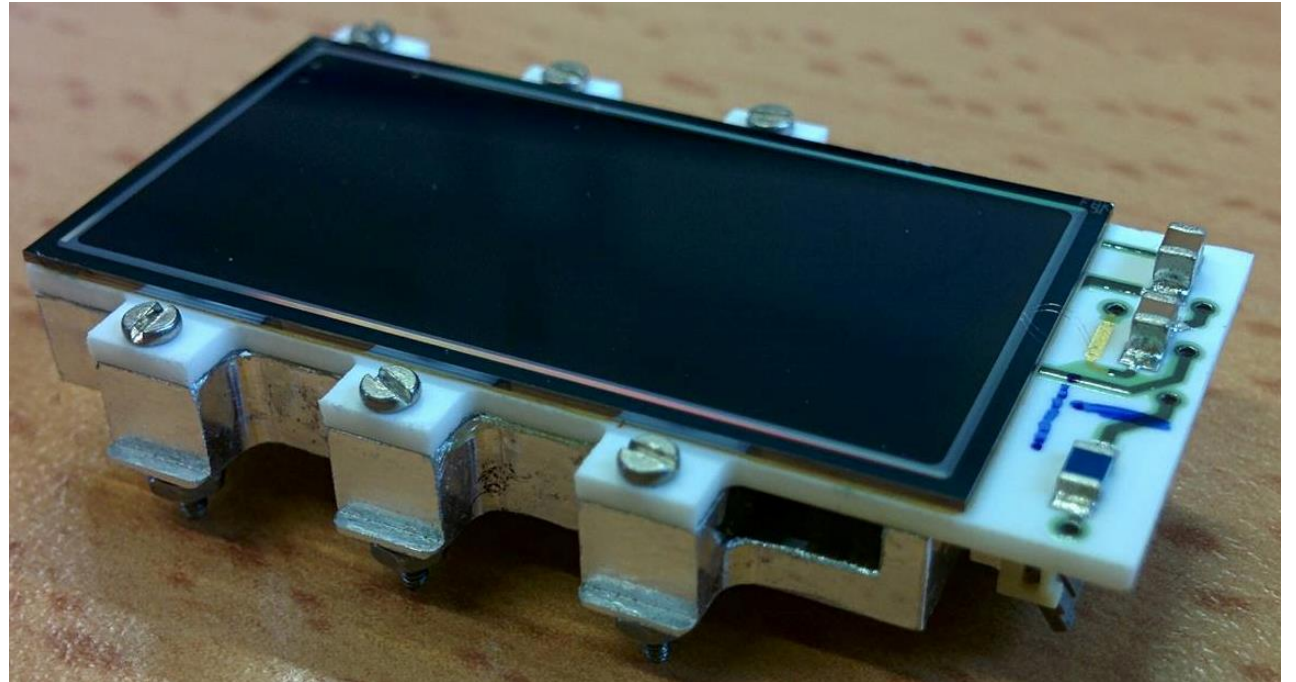


Entrance window side UP

Anode/drift-rings side UP

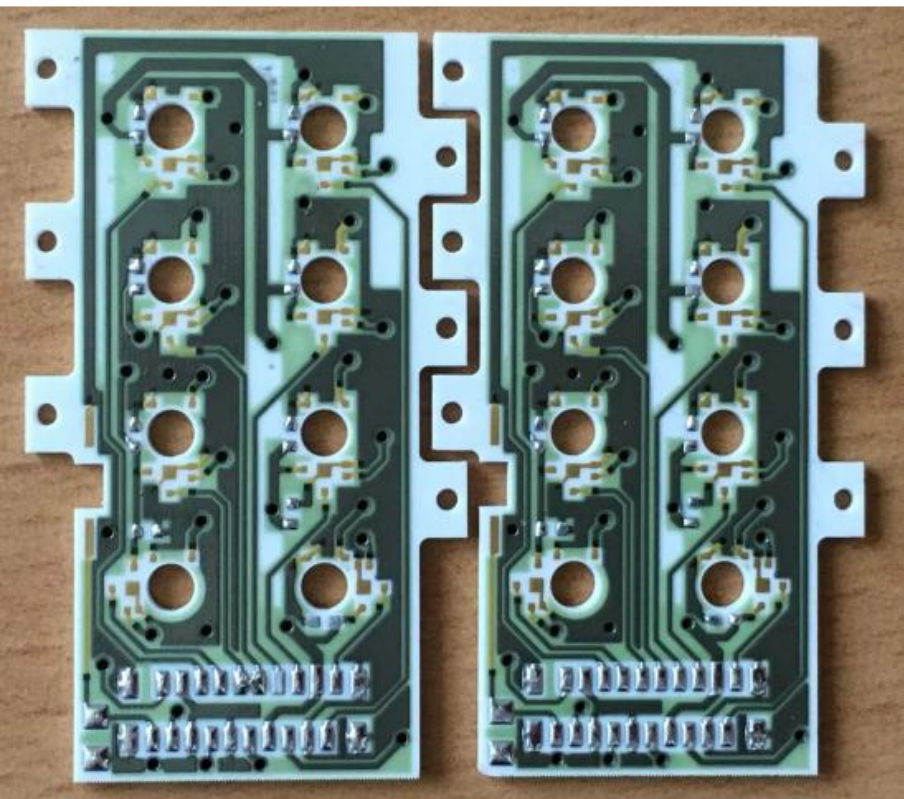
Shipping package

4x2 SDD array - single unit

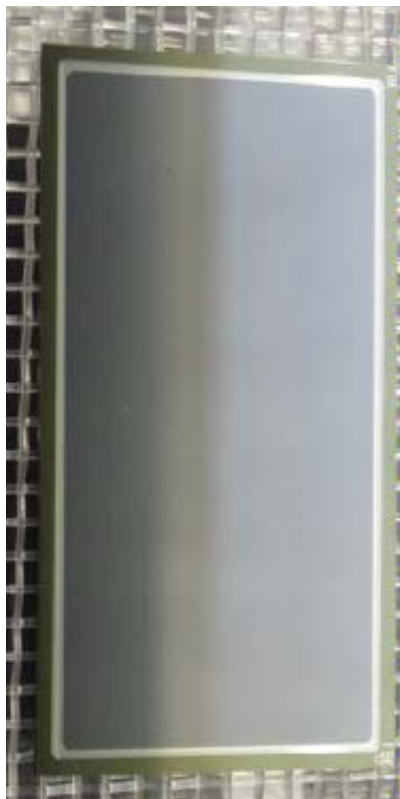


SDD mounting / bonding

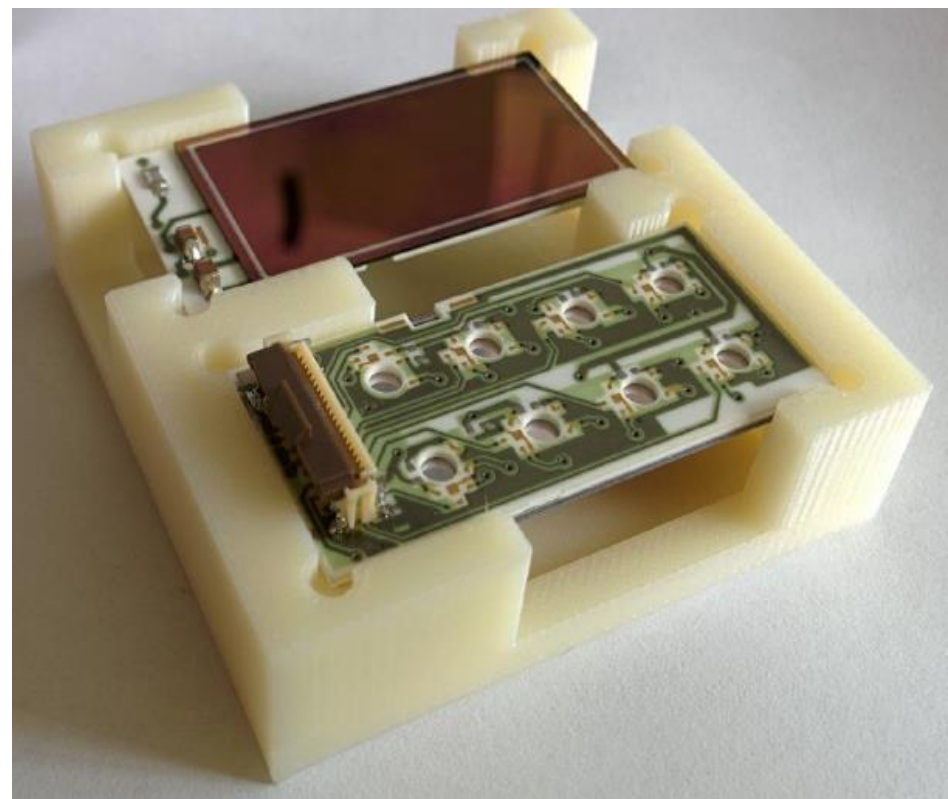
ceramic boards



4x2 SDD chip



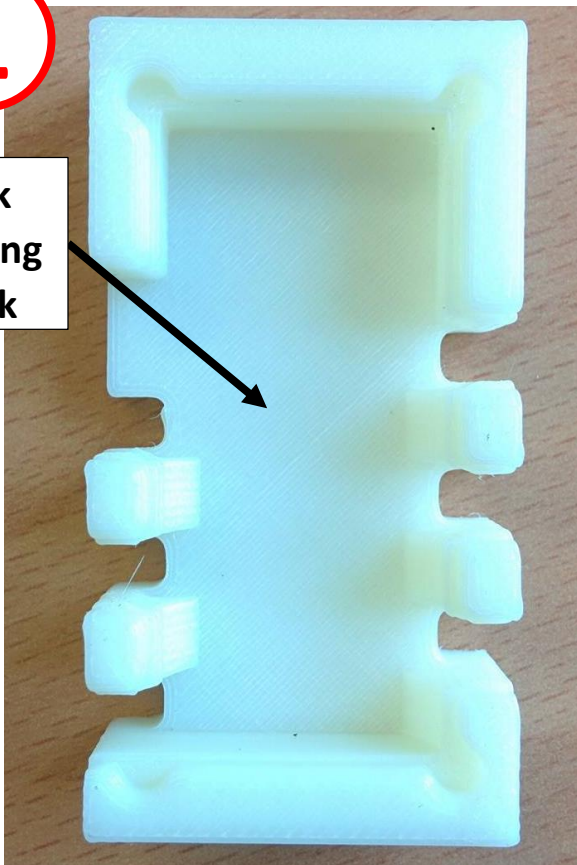
device for gluing and bonding



➤ mounting and bonding process under control

1

Back Bonding Block



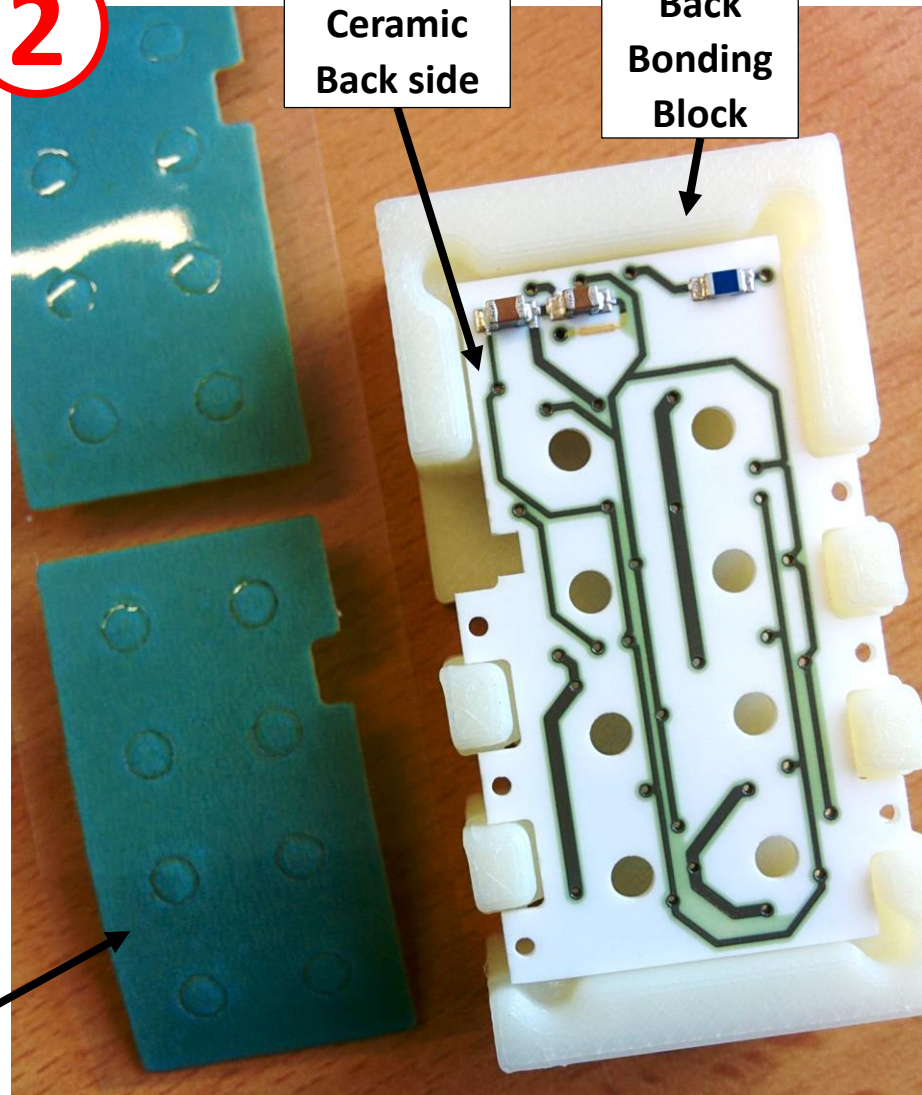
Take the Back bonding block.

Kapton Bi-adhesive foil

2

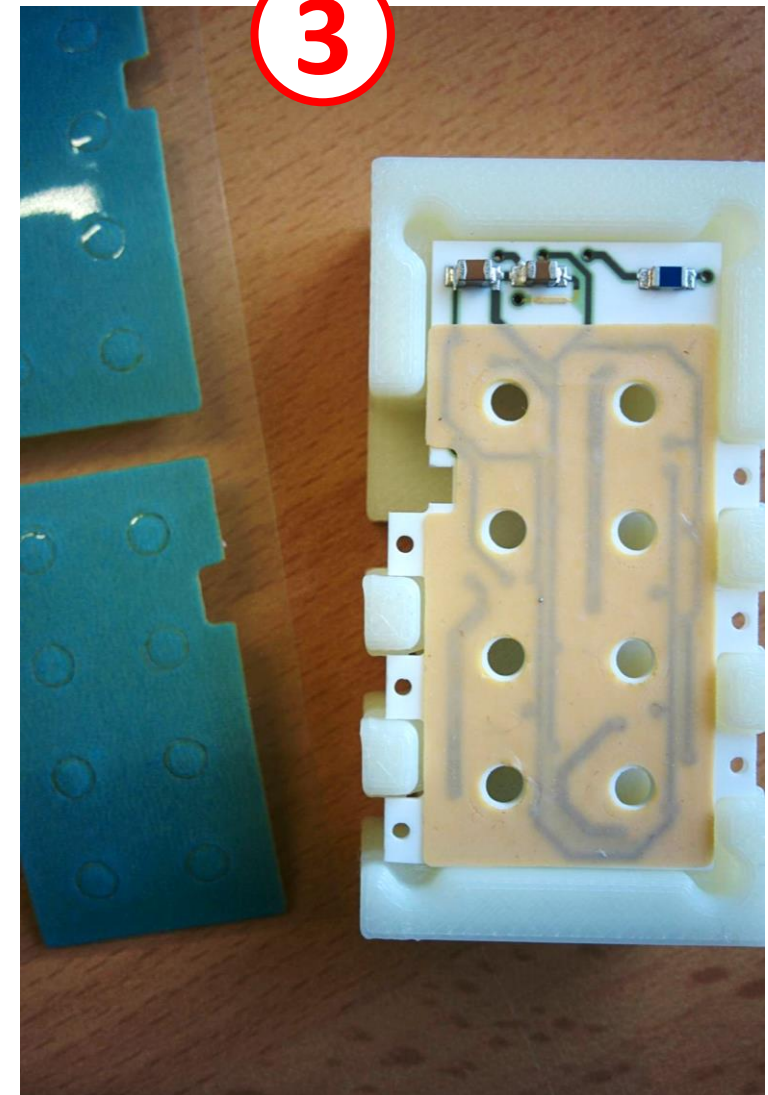
Ceramic Back side

Back Bonding Block



Place the Ceramic board in the back bonding block.

3

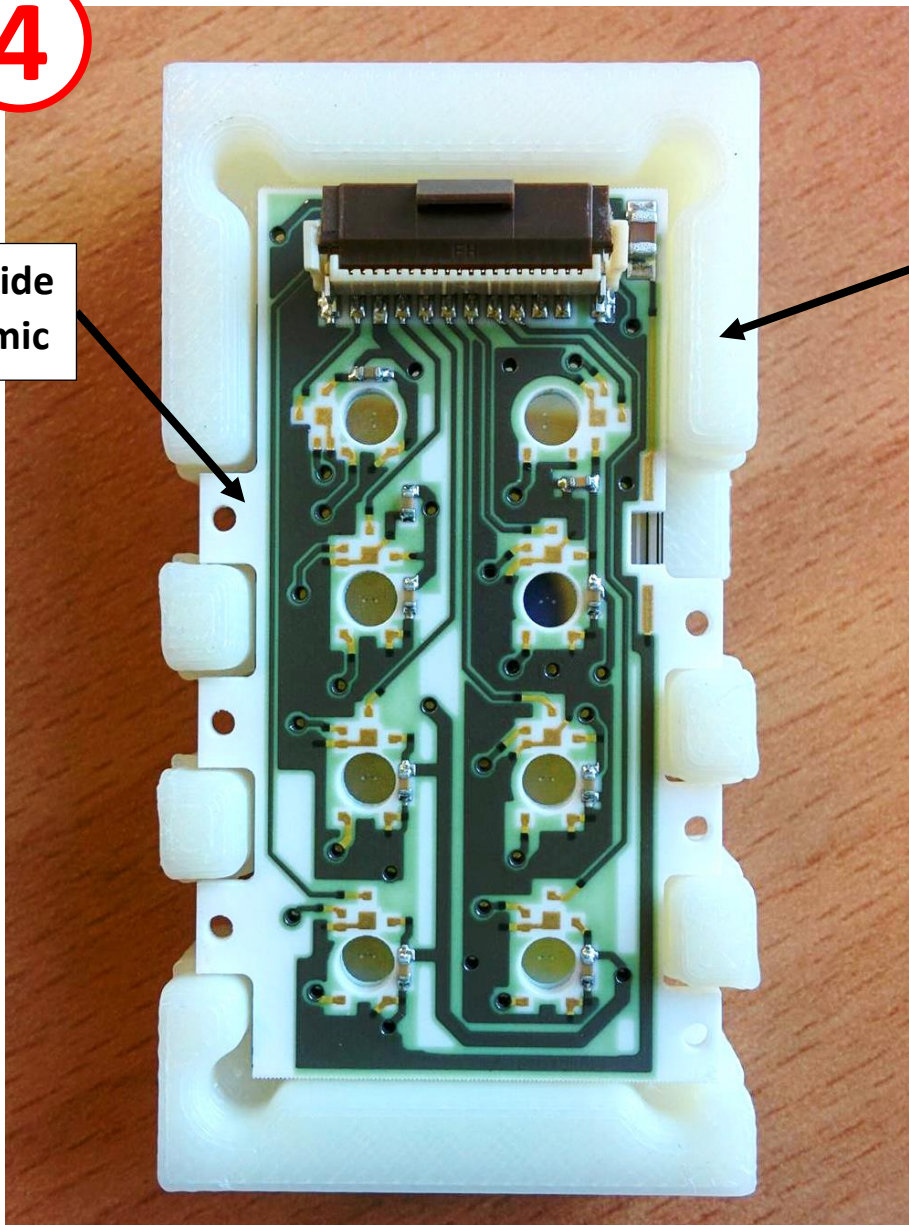


Place the Kapton bi-adhesive correctly on the ceramic back side.

4

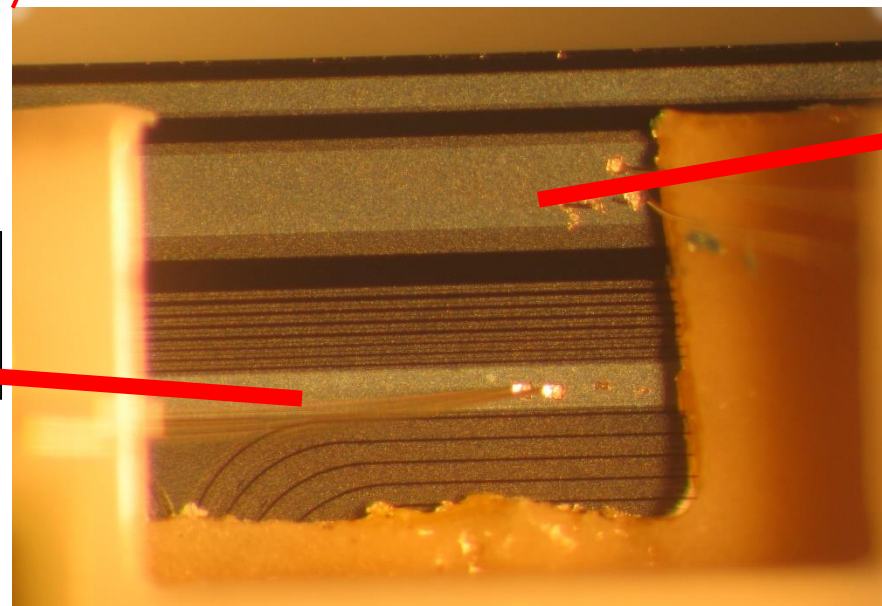
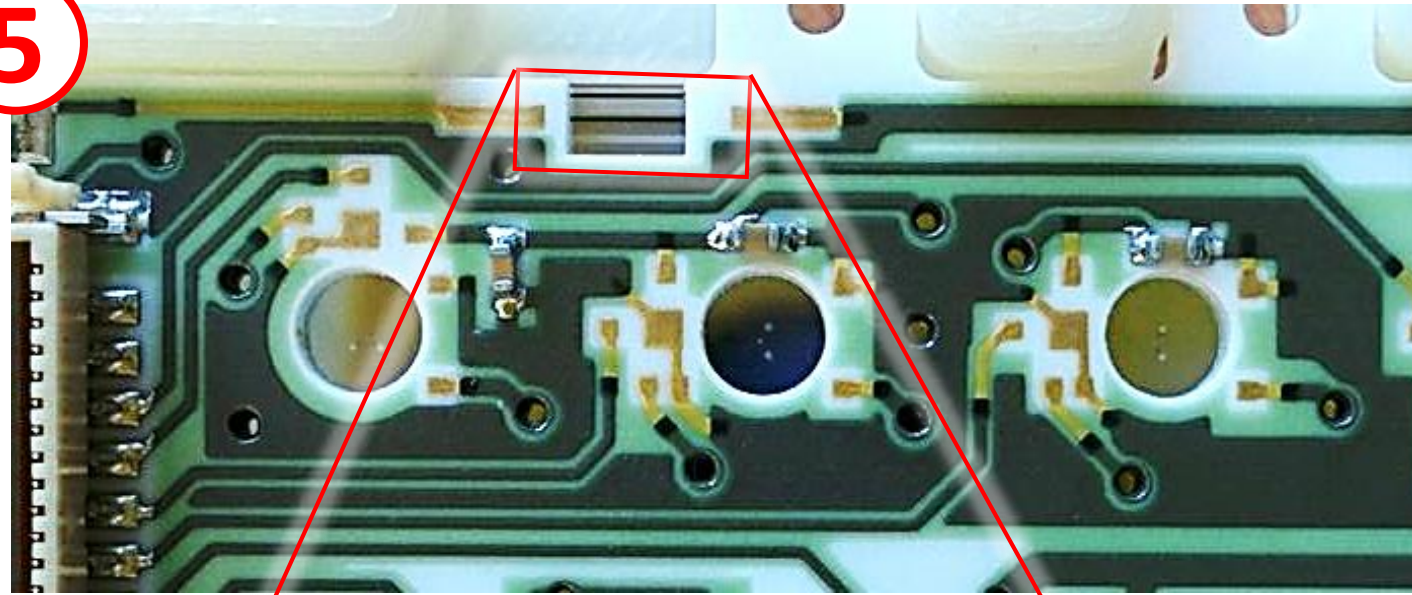
Anode side
of Ceramic

Anode
Bonding
Block



Place the ceramic of step 3 onto the SDD array present in the anode bonding block.

5

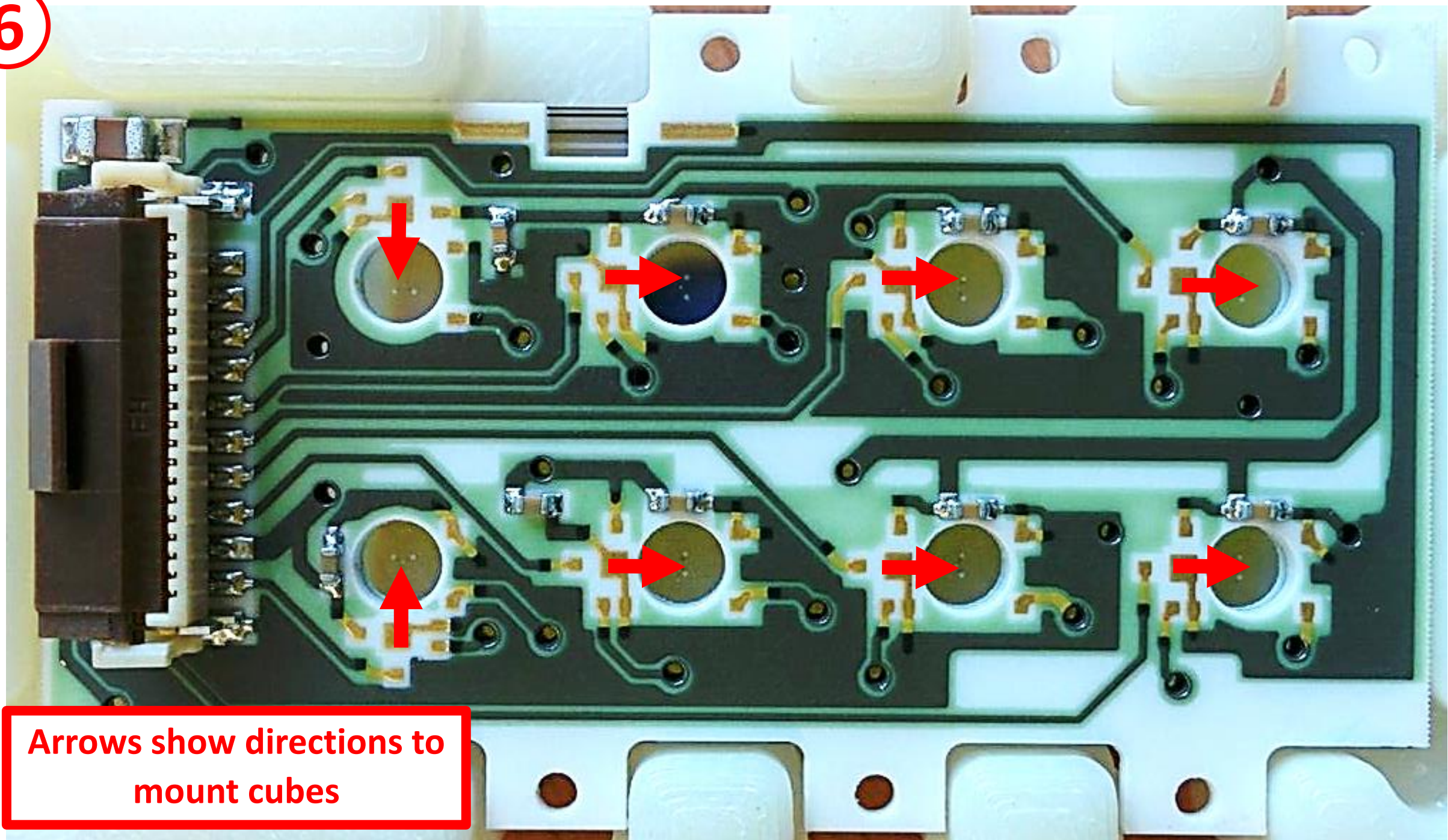


LAST RING

SUB

Ring N and Substrate bonding

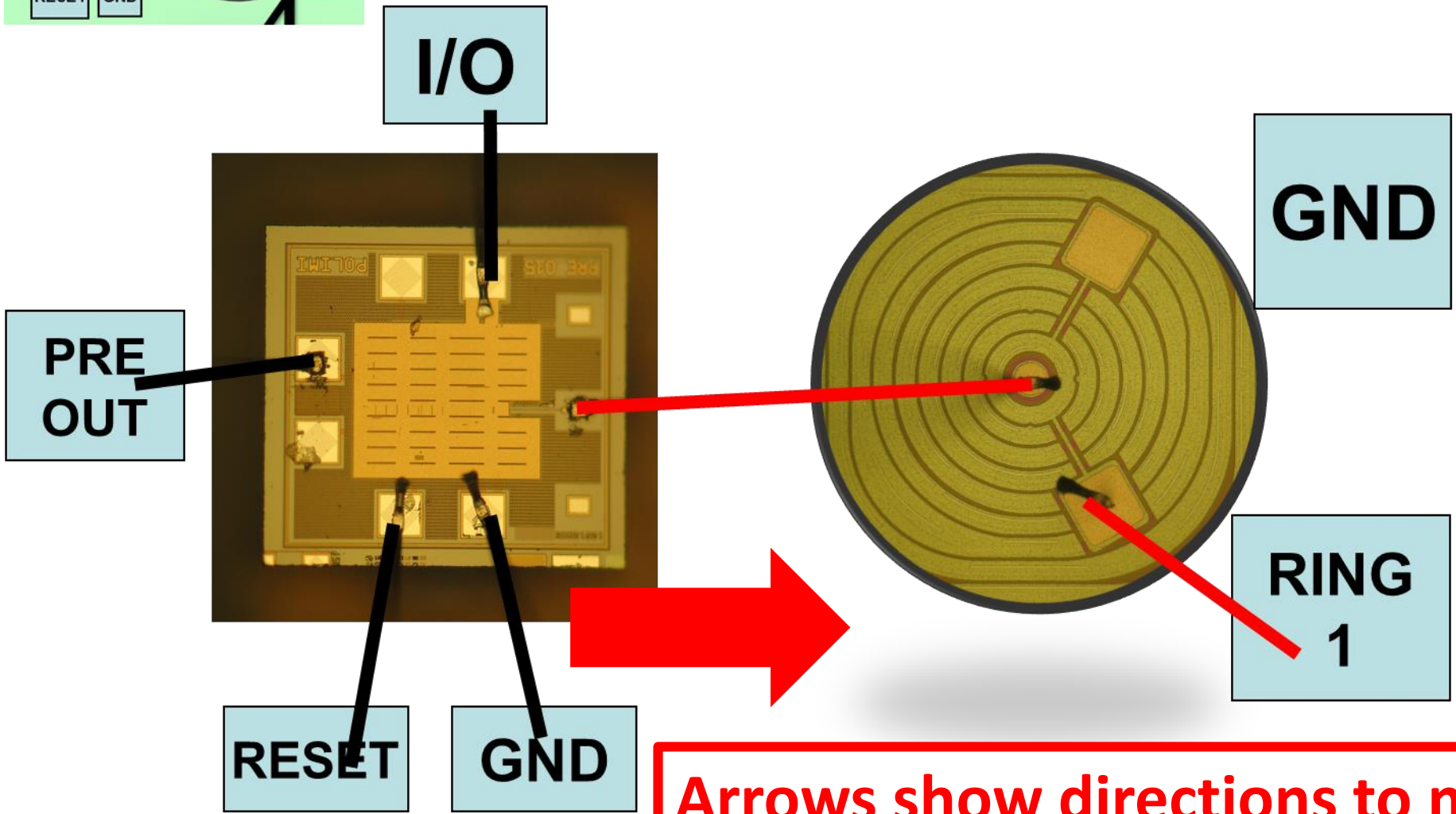
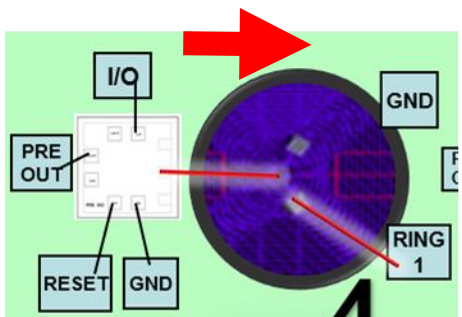
6



Arrows show directions to mount cubes

7

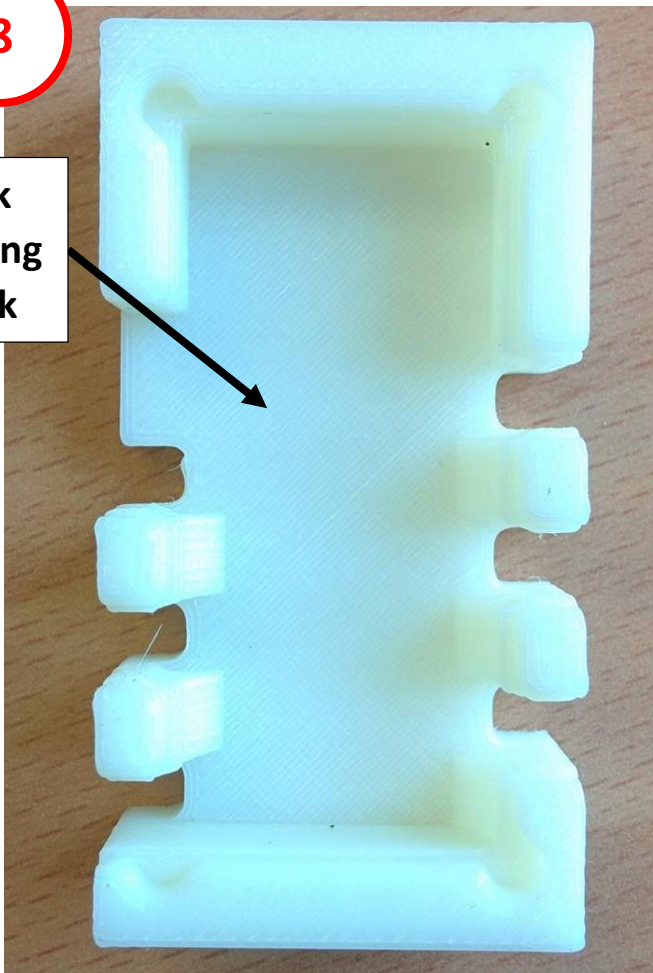
Complete working channel bonding



Arrows show directions to mount cubes

8

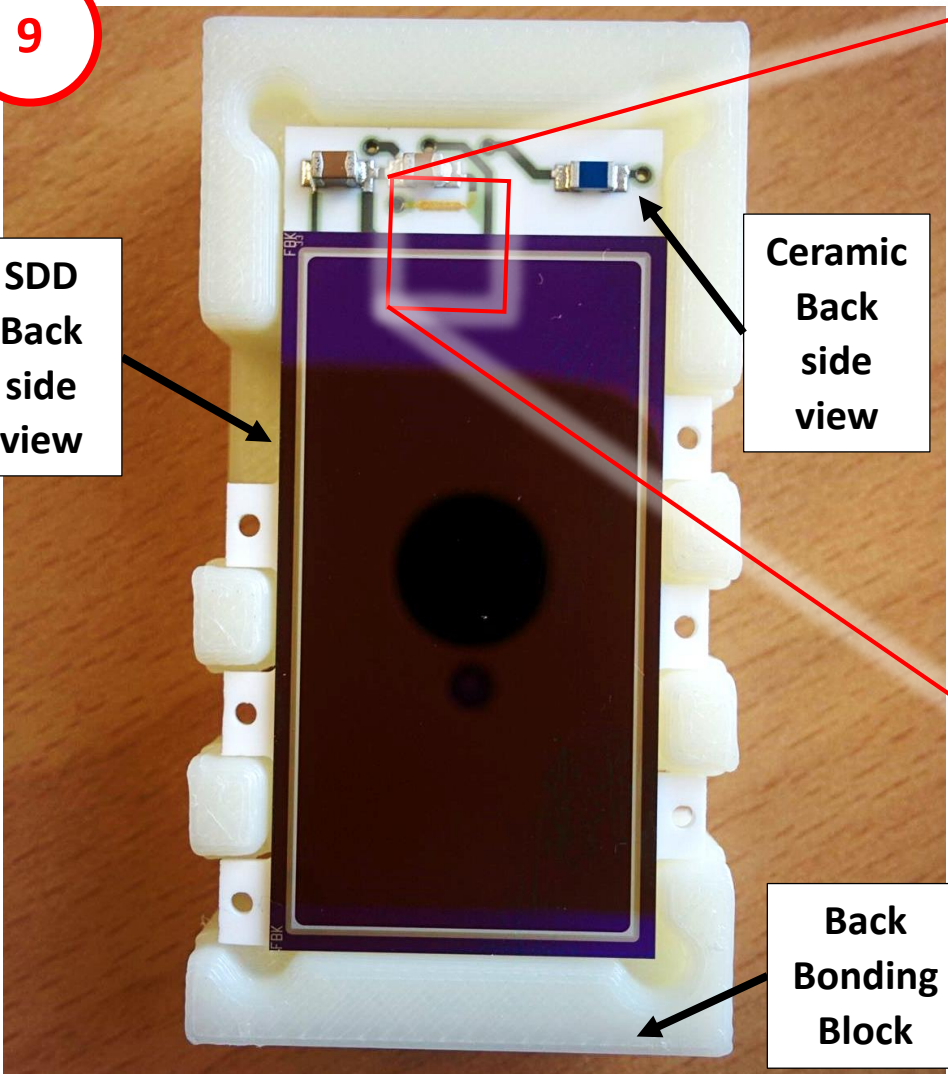
Back Bonding Block



Take the Back bonding block.

9

SDD Back side view

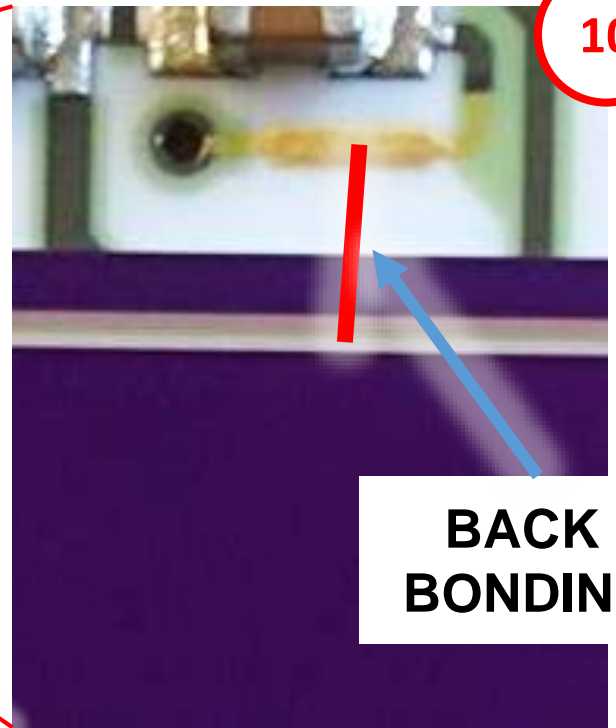


Place the ceramic board with SDD Back side up on the Back bonding block.

Ceramic Back side view

Back Bonding Block

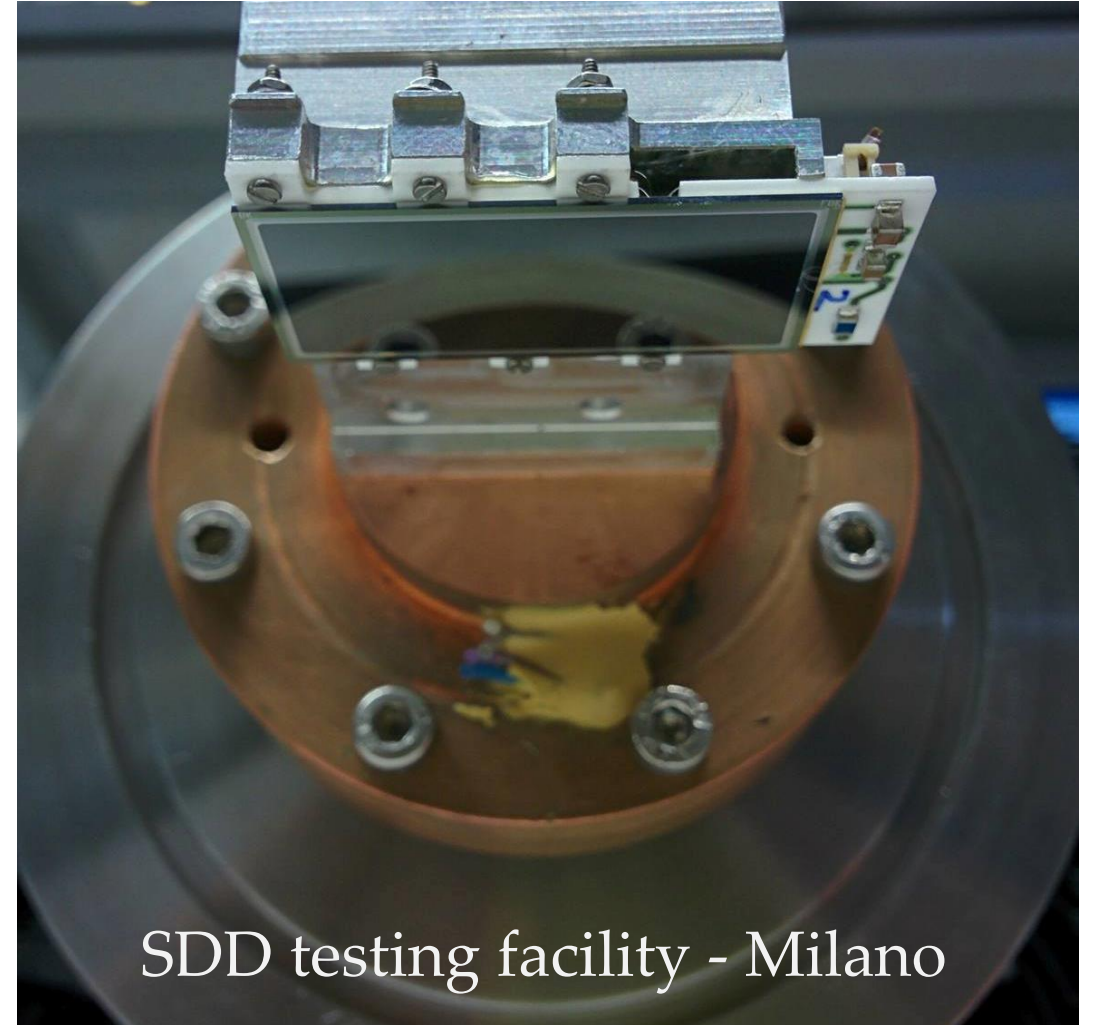
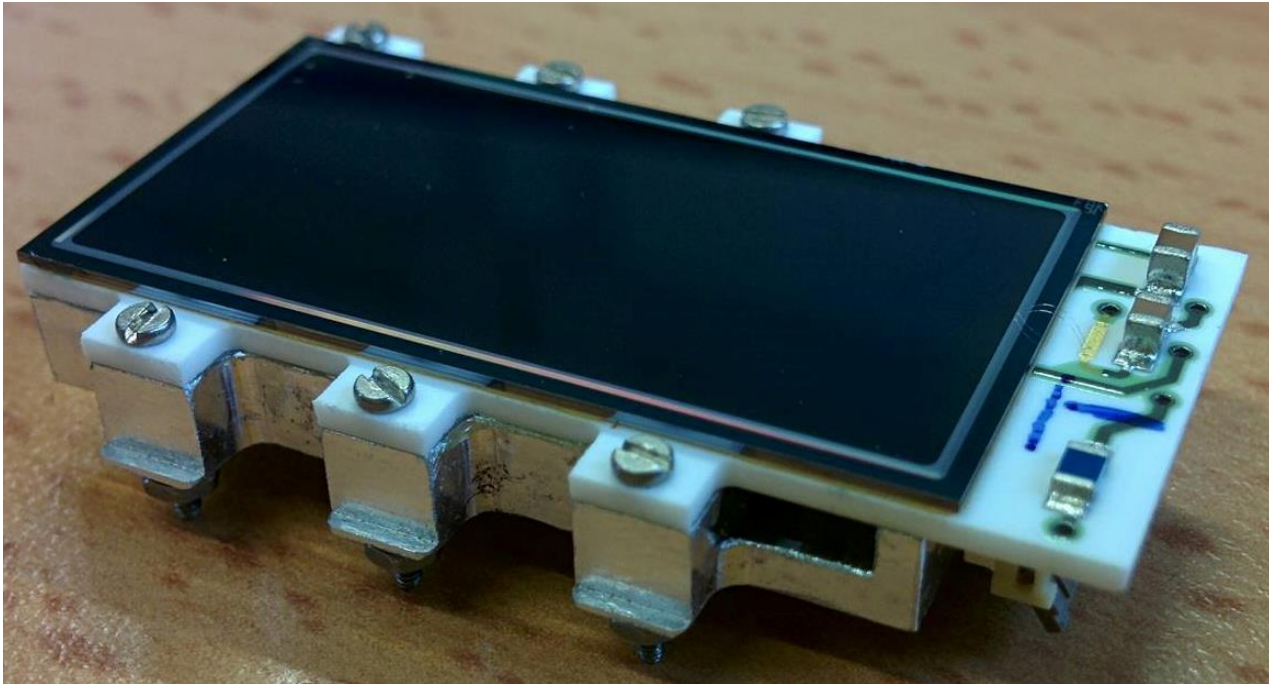
10



BACK BONDING

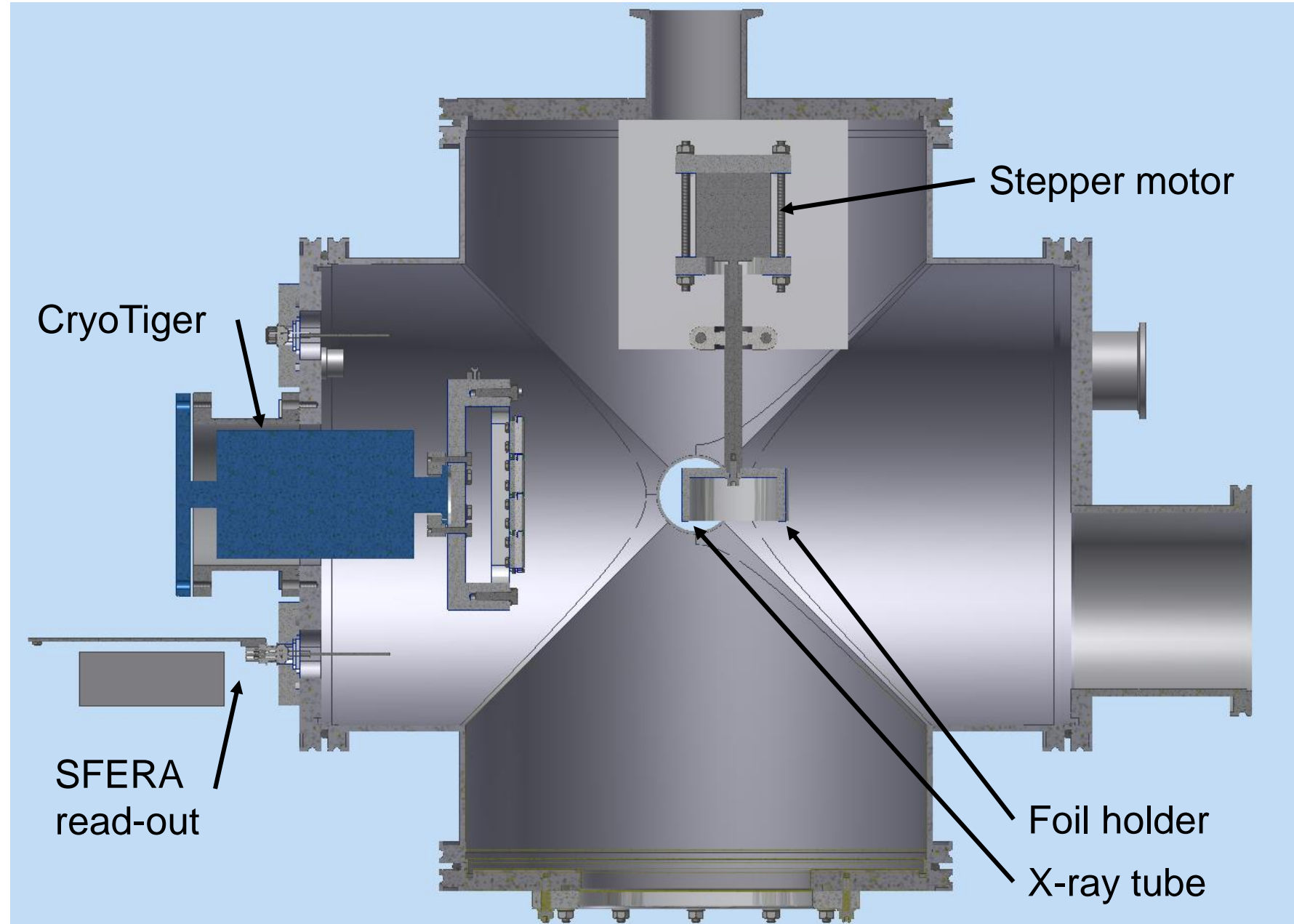
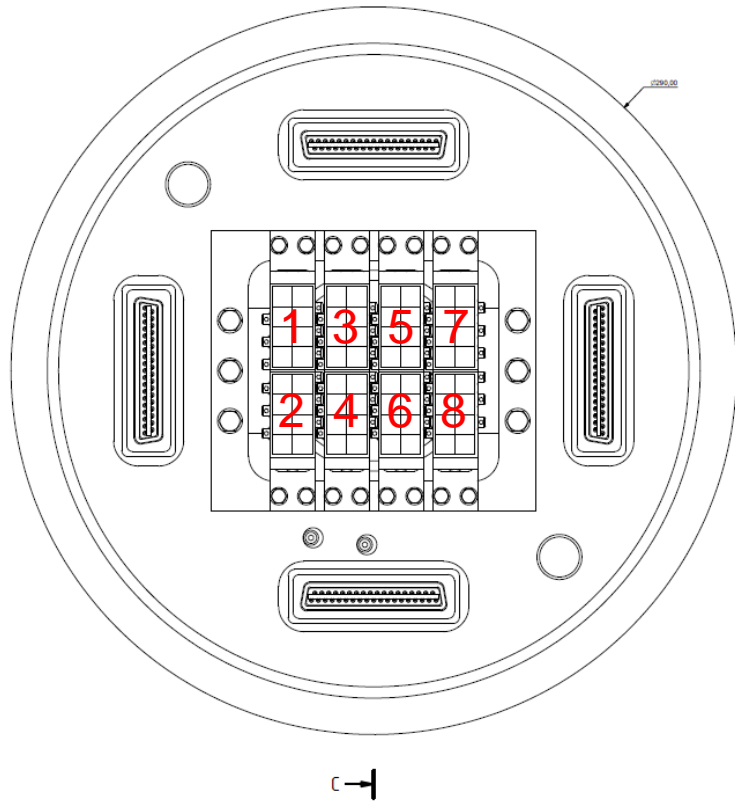
Perform back bonding.

4 x 2 matrix SDD chip - testing

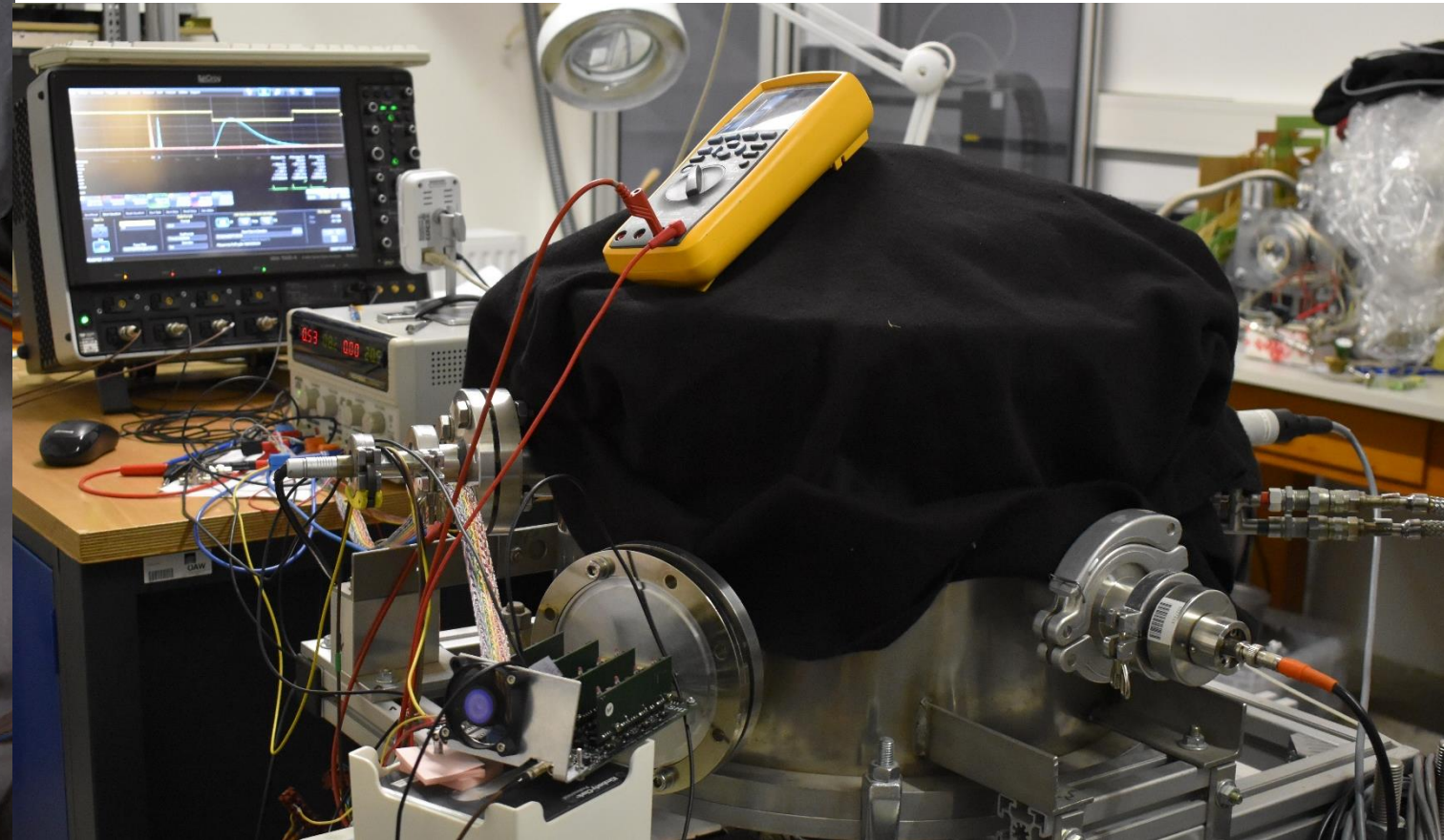
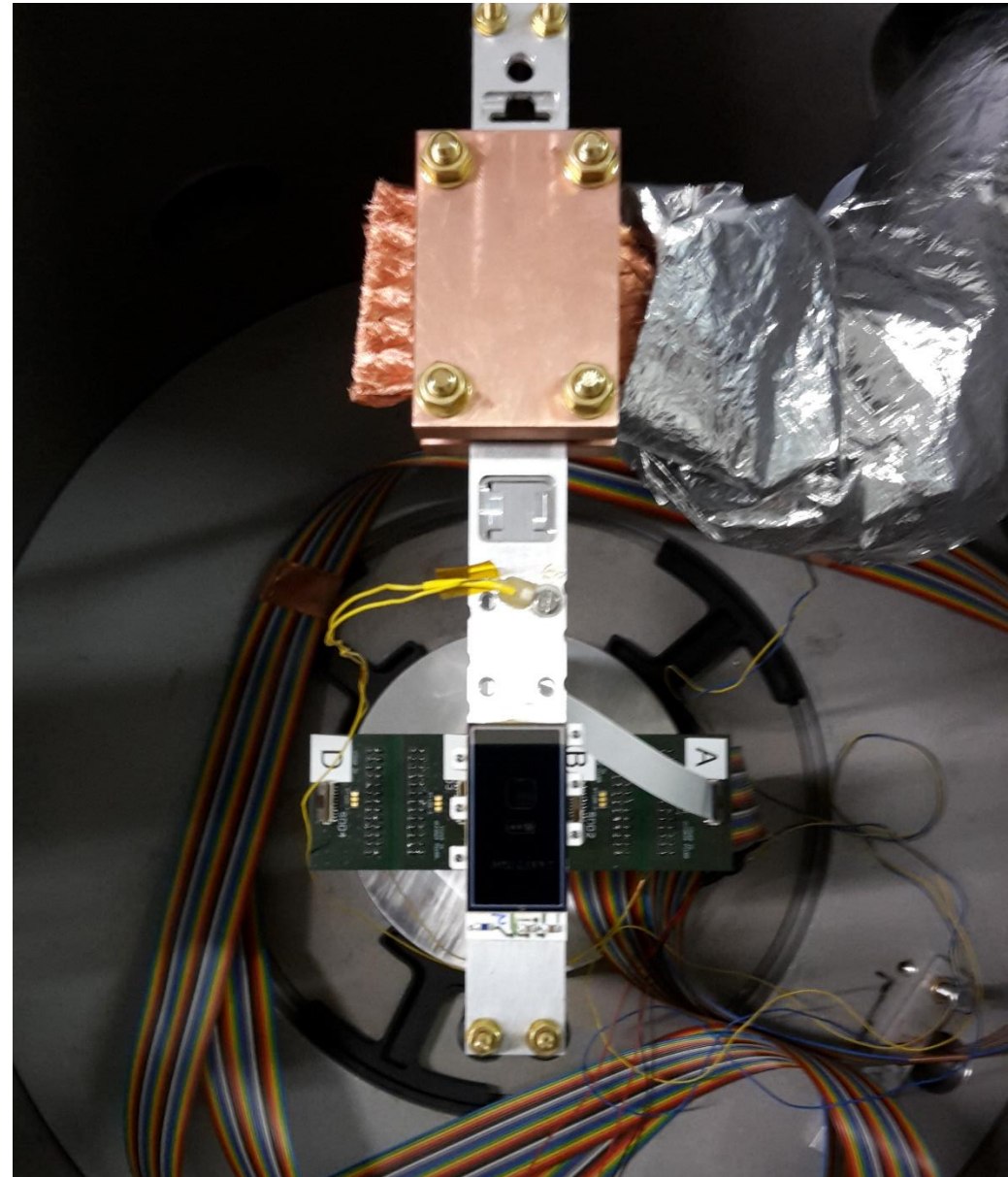


New SDD testing facility - LNF

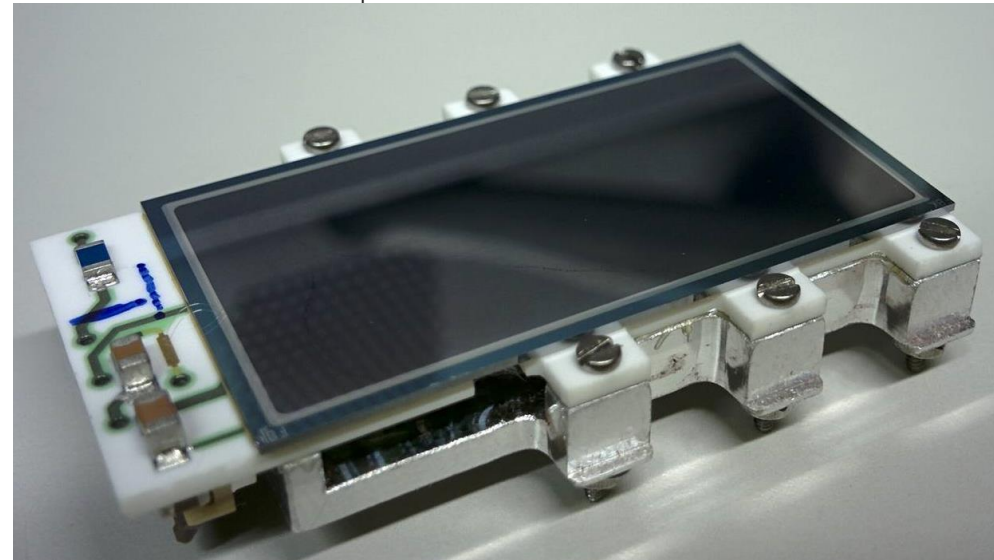
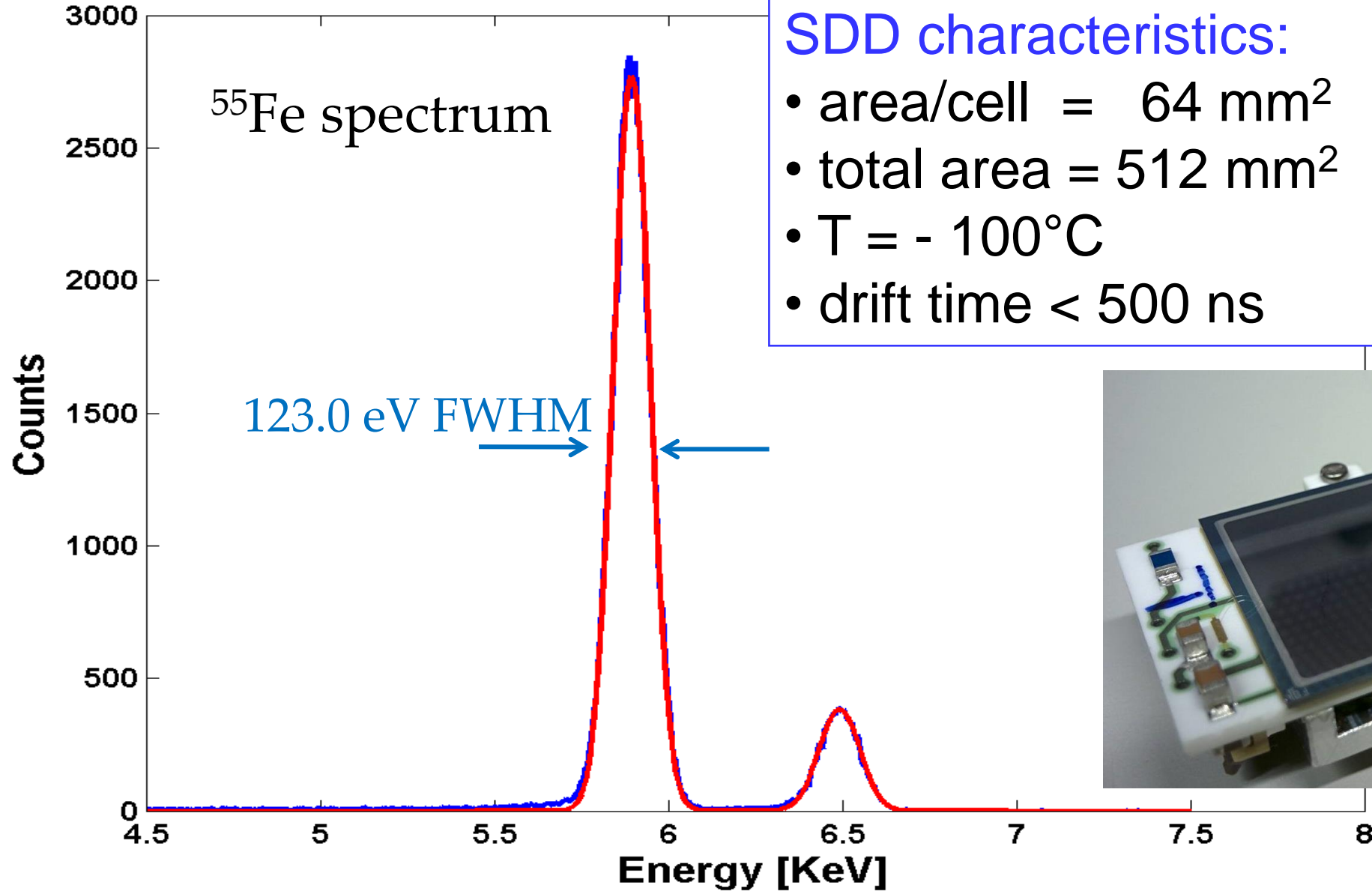
Mounting device for
8 SDD units



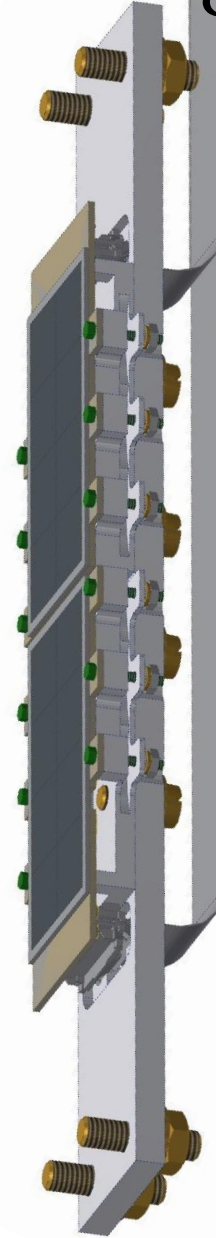
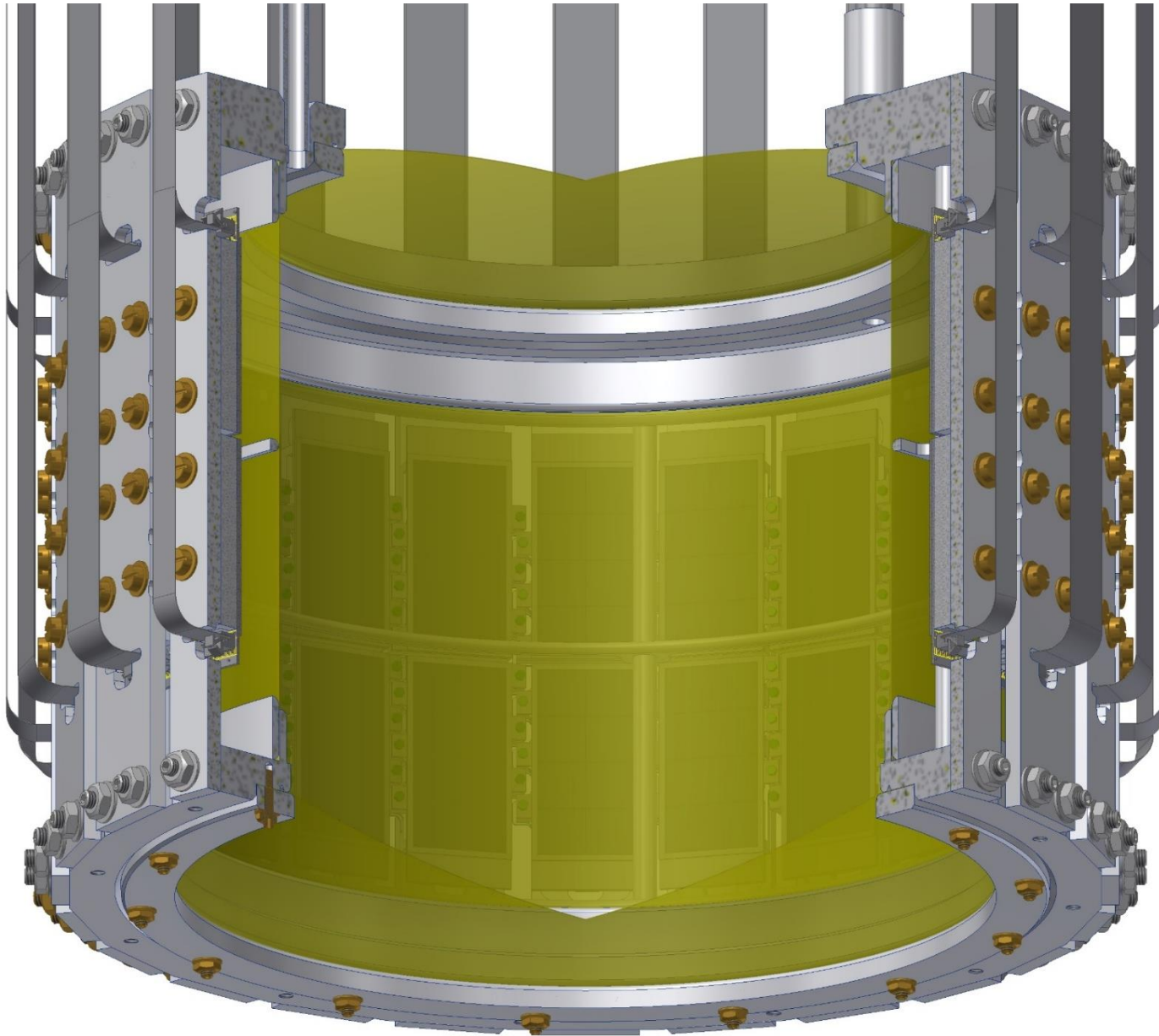
SDD testing facility - SMI



New SDD technology: CUBE preamplifier



4x2 SDD arrays around the cryogenic target



In total 48 SDDs will be used



SDD arrays, delivery and qualification



48 SDDs arrays needed

Delivery status:
52 arrays received

Batch	Wafer	Matrix	Q-index	Batch	Wafer	Matrix	Q-index
SIDDHARTA1b	W01	1,2	8.080	SIDDHARTA1b	W03	1,4	8.080
SIDDHARTA1b	W01	2,1	8.080	SIDDHARTA1b	W03	1,1	8.620
SIDDHARTA1b	W01	3,2	8.080	SIDDHARTA1b	W04	3,2	8.260
SIDDHARTA1b	W01	3,3	8.530	SIDDHARTA1b	W04	2,1	8.611
SIDDHARTA1b	W02	1,4	8.161	SIDDHARTA1b	W04	1,2	8.710
SIDDHARTA1b	W02	3,1	8.800	SIDDHARTA1b	W05	3,4	8.710
SIDDHARTA1b	W02	3,3	8.530	SIDDHARTA1d	W14	3,1	8.080
SIDDHARTA1c	W12	2,1	8.440	SIDDHARTA1d	W14	3,2	8.440
SIDDHARTA1c	W17	1,1	8.080	SIDDHARTA1d	W14	2,1	8.521
				SIDDHARTA1d	W14	3,3	8.620
				SIDDHARTA1d	W15	3,4	8.170
				SIDDHARTA1d	W15	3,1	8.251
				SIDDHARTA1d	W15	3,3	8.260
				SIDDHARTA1d	W15	2,1	8.440
				SIDDHARTA1d	W19	1,2	8.260
				SIDDHARTA1d	W19	3,1	8.260
				SIDDHARTA1d	W19	1,1	8.350
				SIDDHARTA1d	W19	1,4	8.350

Q-index: N.DGS

N = number of functioning channels
(with $J_{\text{anode}} < 2\text{nA/cm}^2$)

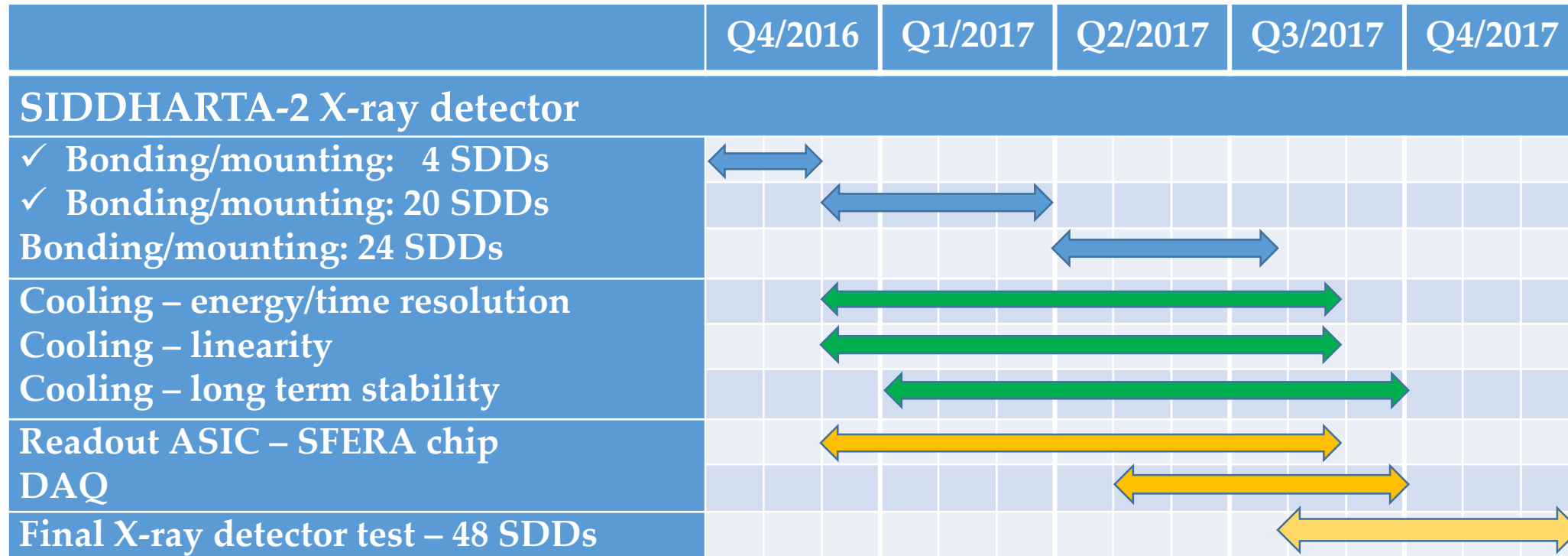
D = number of "diamond" channels
(with $J_{\text{anode}} < 80\text{pA/cm}^2$)

G = number of "gold" channels
(with $J_{\text{anode}} < 250\text{pA/cm}^2$)

S = number of "silver" channels
(with $J_{\text{anode}} < 600\text{pA/cm}^2$)

Table 1: Q-index classification based on anode leakage current density

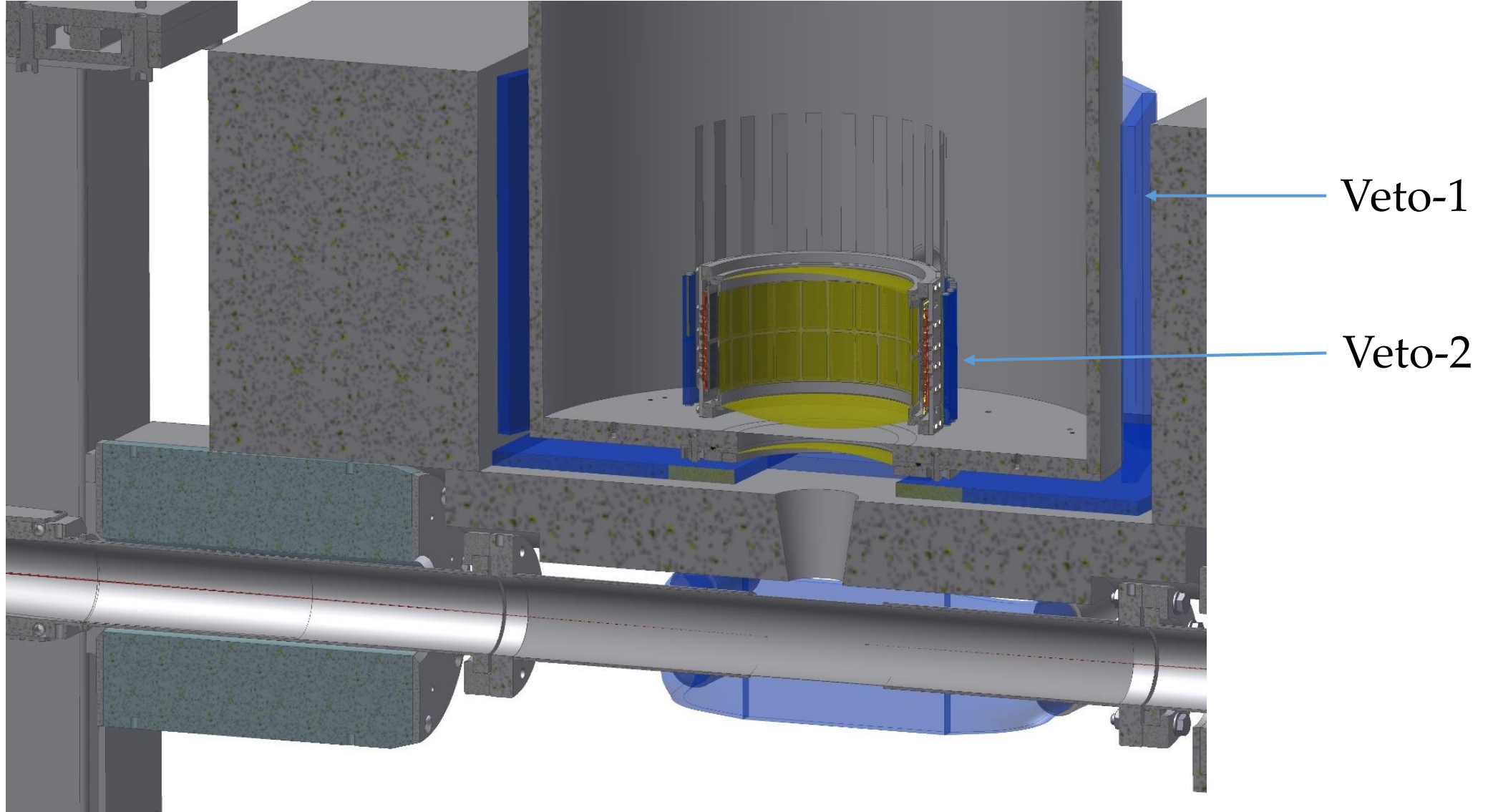
Gantt chart SIDDHARTA-2: X-ray detector



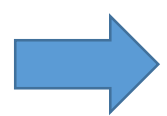
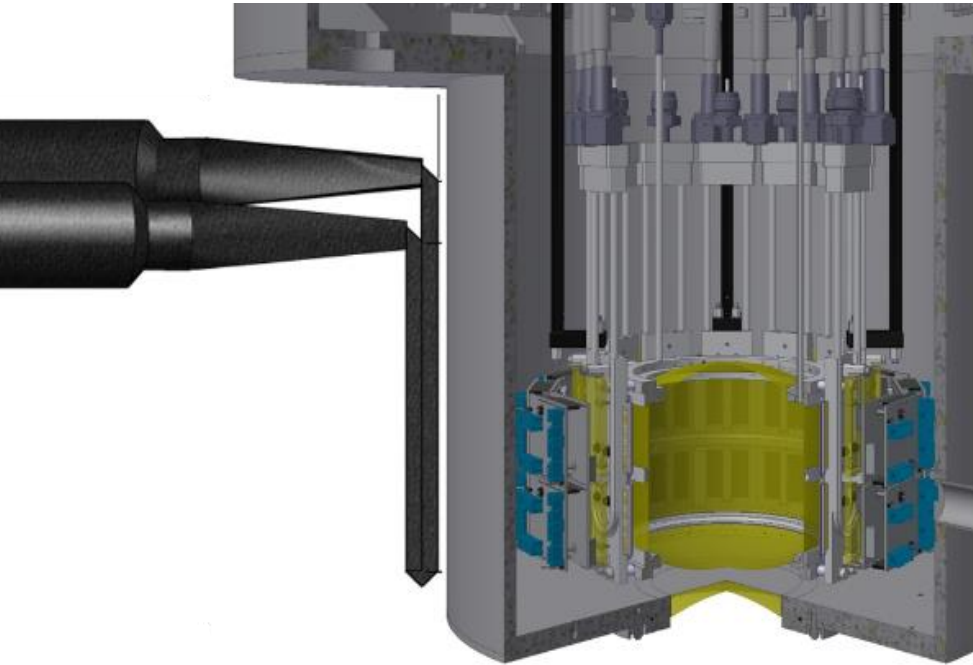
SIDDHARTA-2 setup

➤ the veto system

SIDDHARTA-2 setup: Veto-1 + Veto-2



The veto-1 system

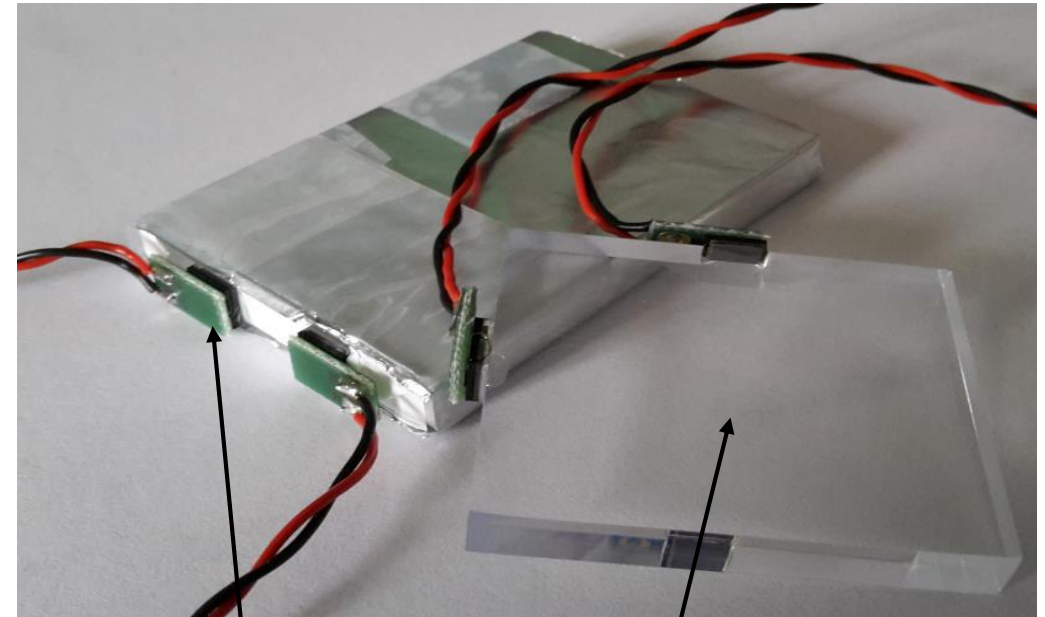
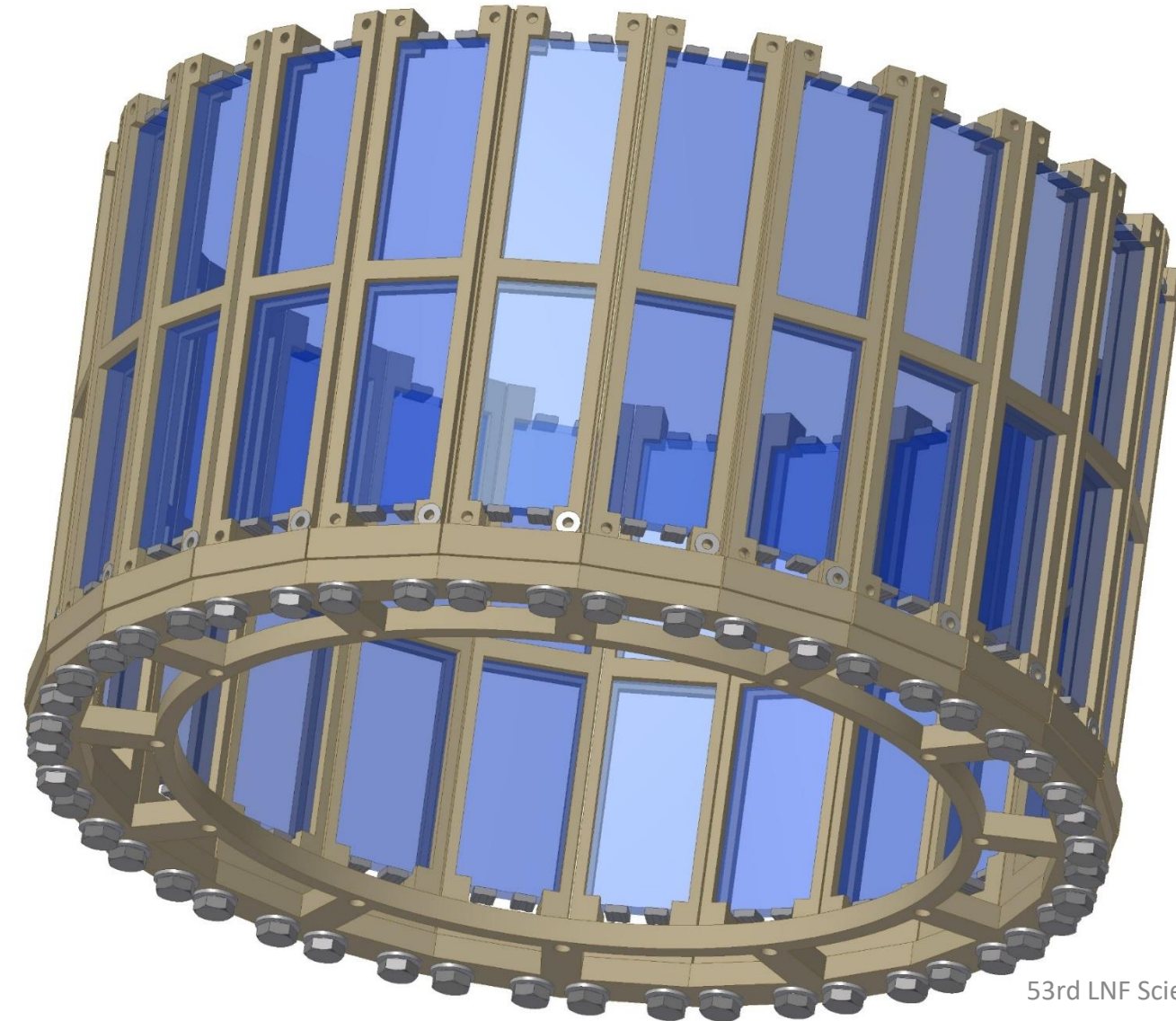


To achieve a good timing resolution, (independent of the “hit” position) < 600 ps (FWHM), the scintillator has to be read out on both side.

Because the available space is limited due to shielding material, the photomultiplier tubes have to be on the same side (a special light-guide mirror design was used).

The veto-2 system

Veto-2 arrangement



SiPM – 4x4
NUV-Trento

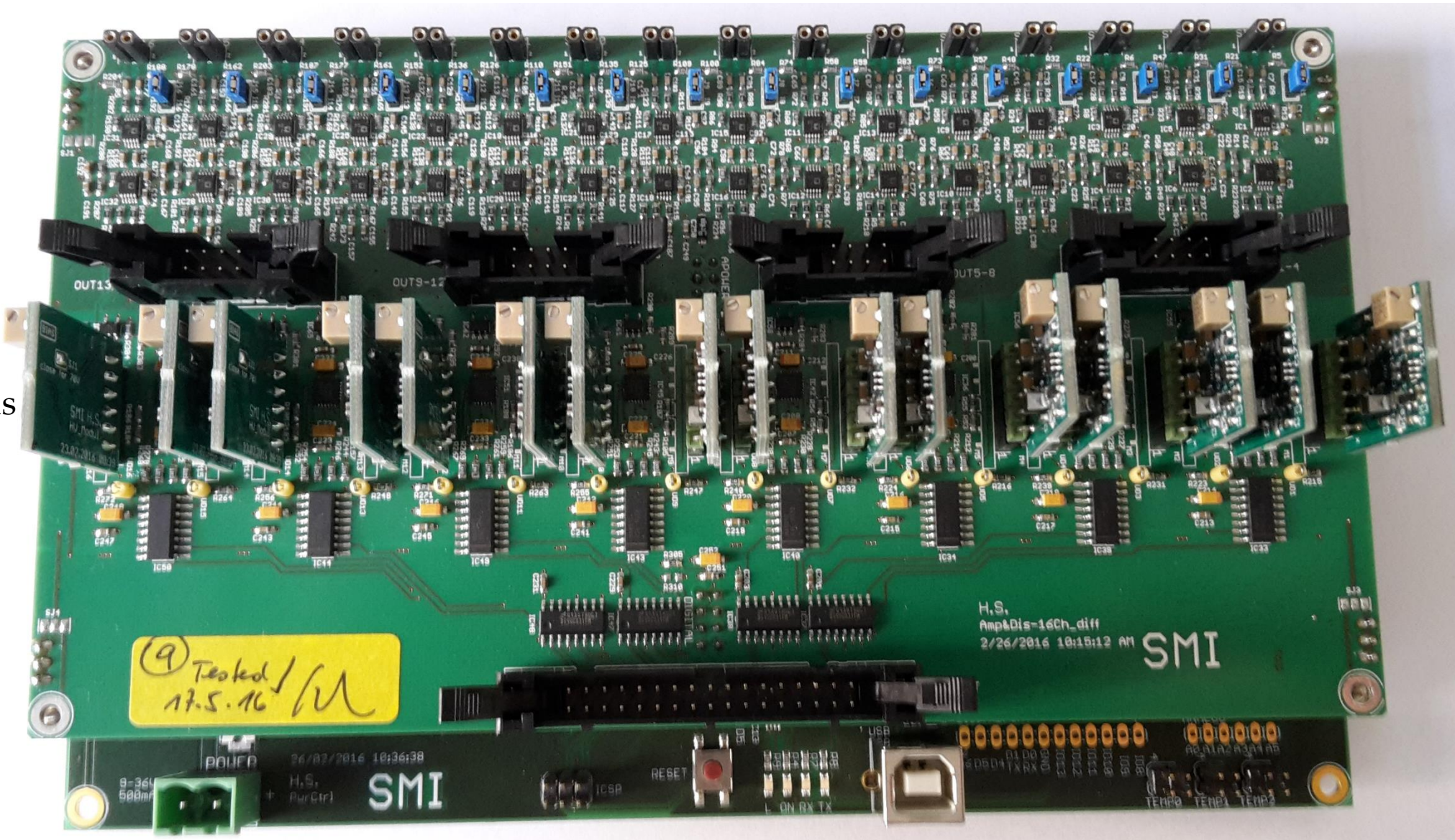
BC-408
scintillator tile

SiPM read-out: the 16-channel IFES board

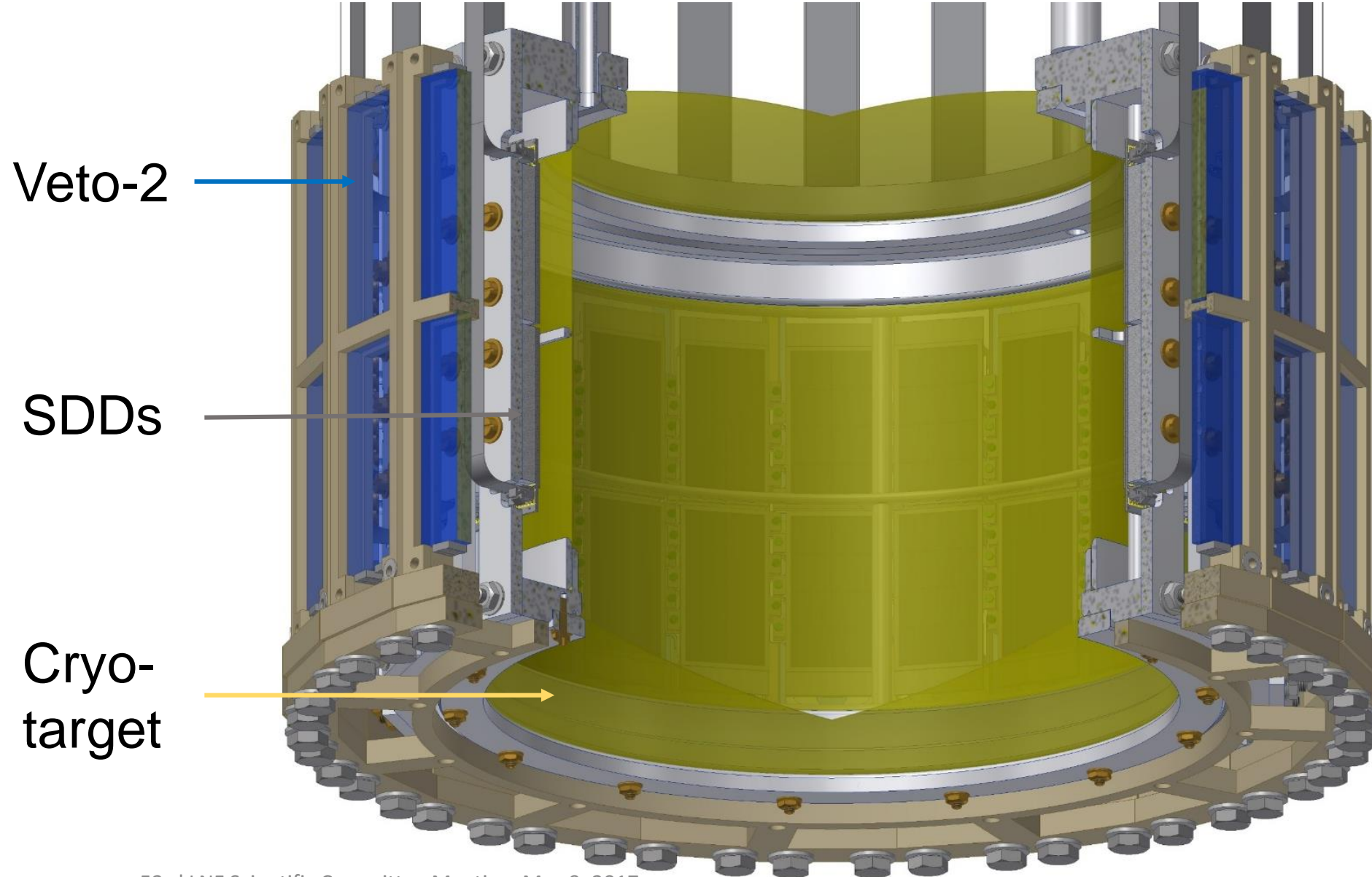
Analogue differential out

Bias voltage boards

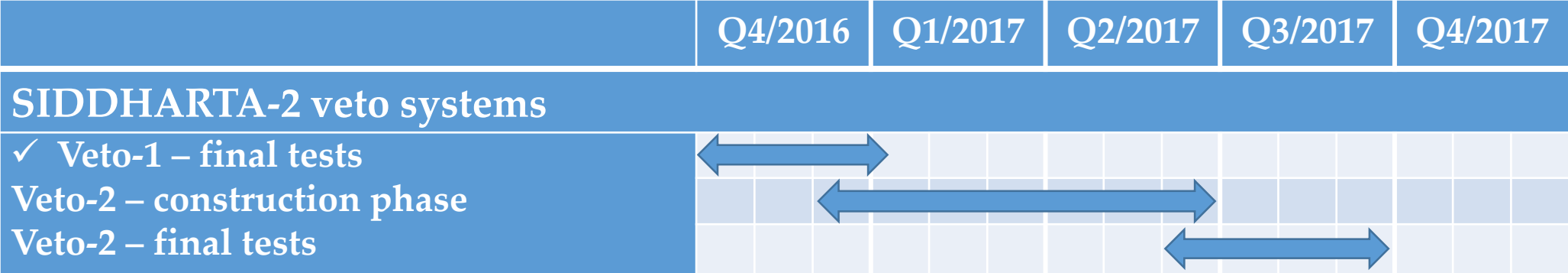
LVDS digital ToT output



Cryogenic target – SDDs – veto-2 arrangement



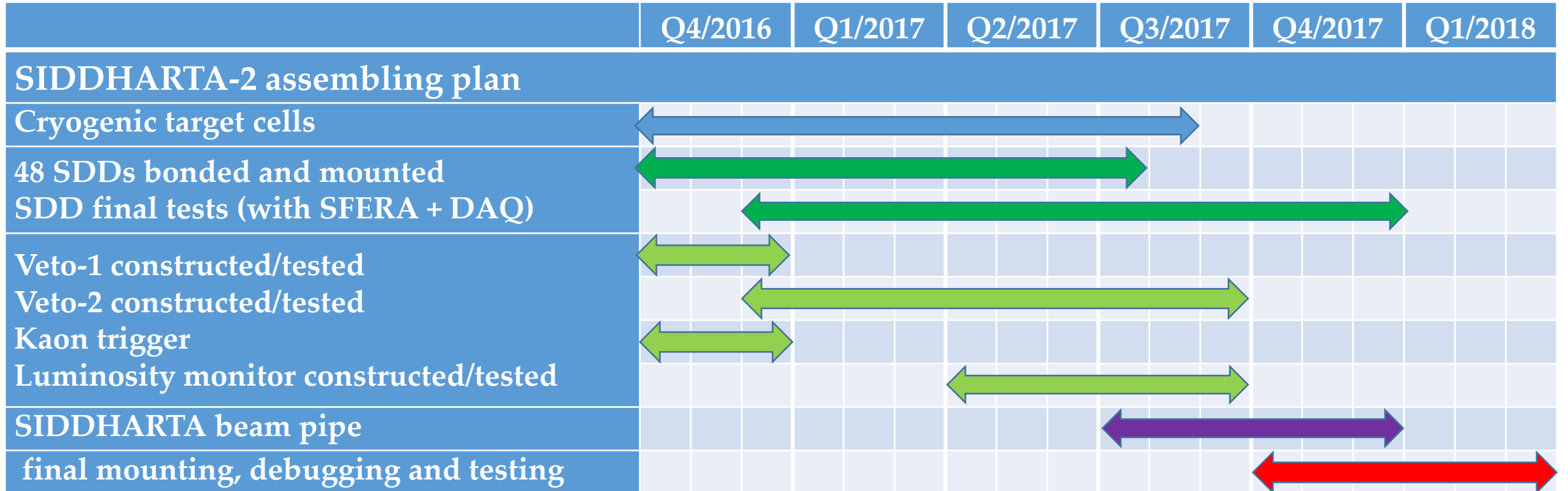
Gantt chart SIDDHARTA-2: Veto systems



SIDDHARTA-2 setup

- Assembling plan
- Installation at DAΦNE

Gantt chart SIDDHARTA-2:



installation
at DAΦNE

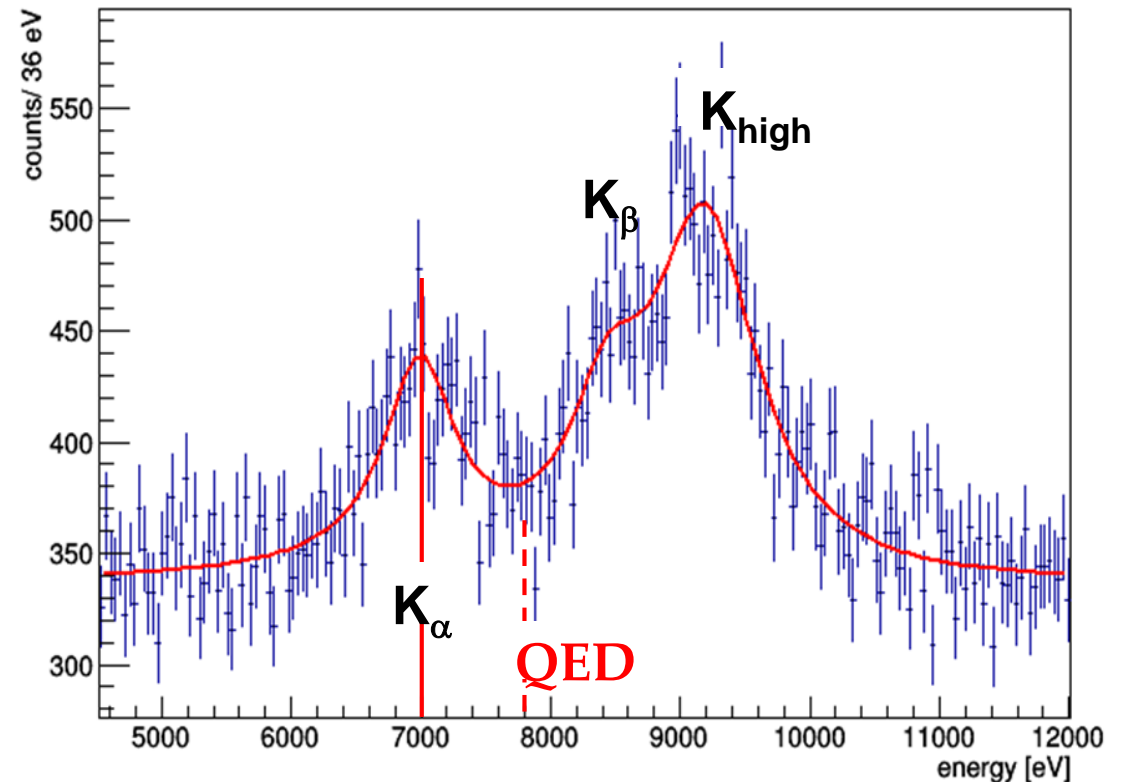
SIDDHARTA-2 plan for the K-d measurement

200 pb⁻¹, to debug and optimize the SIDDHARTA-2 apparatus

800 pb⁻¹, to perform the first measurement of the strong interaction induced energy shift and width of the konic deuterium ground state (similar precision as K-p) !

achievable precision:
shift: 30 eV
width: 75 eV

Plans to secure personal for beam time and analysis is under discussion!



SIDDHARTA-2 future programme and perspectives

- Other light kaonic atoms ($K^- O$, $K^- C$,...)
- Heavier kaonic atoms ($K^- Si$, $K^- Pb$...)
- **Kaonic helium transitions to the 1s level**
- **Kaon mass - precision measurement at a level < 7 keV**
 - Radiative kaon capture – $\Lambda(1405)$ study
 - Investigate the possibility of the measurement of other types of hadronic exotic atoms (sigmonic hydrogen ?)

EXA2017

11-15 SEPTEMBER 2017
AUSTRIAN ACADEMY OF SCIENCES
THEATERSAAL
SONNENFELSGASSE 19
1010 VIENNA, AUSTRIA
EXA2017@OEAW.AC.AT

Constraining the $\bar{K}N$ interaction from the $1S$ level shift of kaonic deuterium

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²*Department of Physics, Kyoto University, Kyoto 606-8502, Japan*

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⁴*Physik-Department, Technische Universität München, 85748 Garching, Germany*

(Dated: April 19, 2017)

EXA2017

INTERNATIONAL CONFERENCE ON EXOTIC ATOMS AND RELATED TOPICS

TOPICS:

- Antihydrogen: CPT and gravity
- Leptonic atoms: QED and gravity
- Kaon-nucleon and kaon-nucleus interaction
- Low-energy QCD
- Precision experiments with atoms, neutrons and charged particles
- Hadron physics with antiprotons
- Hadron physics at LHC
- Future facilities and instrumentation

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